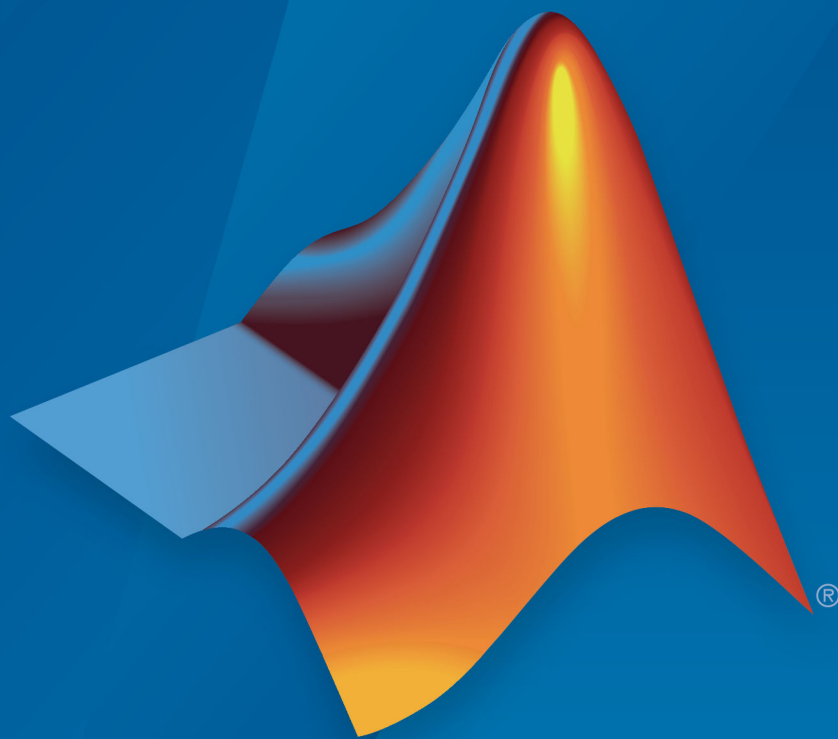


Simscape™ Electronics™

User's Guide



MATLAB® & SIMULINK®

R2018a



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Simscape™ Electronics™ User's Guide

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Modeling an Electronic System

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Getting Started

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Simscape Electronics Product Description

Model and simulate electronic and mechatronic systems

Simscape Electronics provides component libraries for modeling and simulating electronic and mechatronic systems. It includes models of semiconductors, motors, drives, sensors, and actuators. You can use these components to develop electromechanical actuation systems and to build behavioral models for evaluating analog circuit architectures in Simulink®. You can integrate mechanical, hydraulic, pneumatic, and other physical systems into your model using components from the Simscape family of products.

Simscape Electronics helps you develop control algorithms in electronic and mechatronic systems, including vehicle body electronics, aircraft servomechanisms, and audio power amplifiers. The semiconductor models include nonlinear and dynamic temperature effects, enabling you to select components in amplifiers, motor drives, analog-to-digital converters, phase-locked loops, and other circuits. You can parameterize your models using MATLAB® variables and expressions. To deploy models to other simulation environments, including hardware-in-the-loop (HIL) systems, Simscape Electronics supports C-code generation.

Key Features

- Libraries of electronic and electromechanical components with physical connections, including sensors, semiconductors, and actuators
- Parameterization options, enabling entry of key parameter values directly from industry data sheets
- Semiconductor and motor models with temperature-dependent behavior and configurable thermal ports
- Adjustable model fidelity, including nonlinear effects, operational limits, and fault modeling
- MATLAB based Simscape language for creating custom component models
- Access to Simscape linearization and steady-state calculation capabilities
- Support for C-code generation (with Simulink Coder™)

Simscape Electronics Assumptions and Limitations

Simscape Electronics contains blocks that let you model electronic and mechatronic systems at a speed and level of fidelity that is appropriate for system-level analysis. The blocks let you perform tradeoff analyses to optimize system design, for example, by testing various algorithms with different circuit implementations. The library contains blocks that use either high-level or more detailed models to simulate components. Simscape Electronics does not have the capability to:

- Model large circuits with dozens of analog components, such as a complete transceiver.
- Perform either layout (physical design) tasks, or the associated implementation tasks such as layout versus schematic (LVS), design rule checking (DRC), parasitic extraction, and back annotation.
- Model 3-D parasitic effects that are typically important for high-frequency applications.

For these types of requirements, you must use an EDA package specifically designed for the implementation of analog circuits.

Another MathWorks® product, Simscape Power Systems™ software, is better suited for power system networks where:

- The underlying equations are predominantly linear (e.g., transmission lines and linear machine models).
- Three-phase motors and generators are used.

Simscape Power Systems has blocks and solvers specifically designed for these types of applications.

Modeling Physical Networks with Simscape Electronics Blocks

Simscape Electronics is part of the Simulink Physical Modeling family. Models using Simscape Electronics are essentially Simscape block diagrams. To build a system-level model with electrical blocks, use a combination of Simscape Electronics blocks and other Simscape and Simulink blocks. You can connect Simscape Electronics blocks directly to Simscape blocks. You can connect Simulink blocks through the Simulink-PS Converter and PS-Simulink Converter blocks from the Simscape Utilities library. These blocks convert electrical signals to and from Simulink mathematical signals. For more information about connecting different types of blocks, see “Connector Ports and Connection Lines” (Simscape) and “Connecting Simscape Diagrams to Simulink Sources and Scopes” (Simscape).

For more information about basic principles to follow when building an electrical model with Simscape Electronics, see “Basic Principles of Modeling Physical Networks” (Simscape).

Required and Related Products

Product Requirements

Simscape Electronics software is an extension of Simscape product, expanding its capabilities to model and simulate electronic and electromechanical elements and devices.

Simscape Electronics software requires these products:

- MATLAB
- Simulink
- Simscape

Other Related Products

The Simscape Electronics product page at the MathWorks Web site lists the toolboxes and blocksets that extend the capabilities of MATLAB and Simulink. These products can enhance your use of Simscape Electronics software in various applications.

For more information about MathWorks software products, see:

- The online documentation for that product if it is installed
- The MathWorks Web site at www.mathworks.com

Simscape Electronics Block Libraries

In this section...
“Overview of Simscape Electronics Libraries” on page 1-6
“Opening Simscape Electronics Libraries” on page 1-6

Overview of Simscape Electronics Libraries

Simscape Electronics libraries provide blocks for modeling electromechanical and electrical systems within the Simulink environment. You can also create custom components either by combining Simscape Electronics components as Simulink subsystems, or by using the Simscape language (Simscape).

Note Simscape Electronics follows the standard Simulink conventions where block inputs and outputs are called *ports*. In Simscape Electronics, each port represents a single electrical terminal.

A Simscape Electronics model can contain blocks from the standard Simscape Electronics library, from the Simscape Foundation and Utilities libraries, or from a custom library you create, using the Simscape language, based on the Simscape Foundation electrical domain (Simscape). A model can also include blocks from other Simscape add-on products, as well as Simulink blocks.

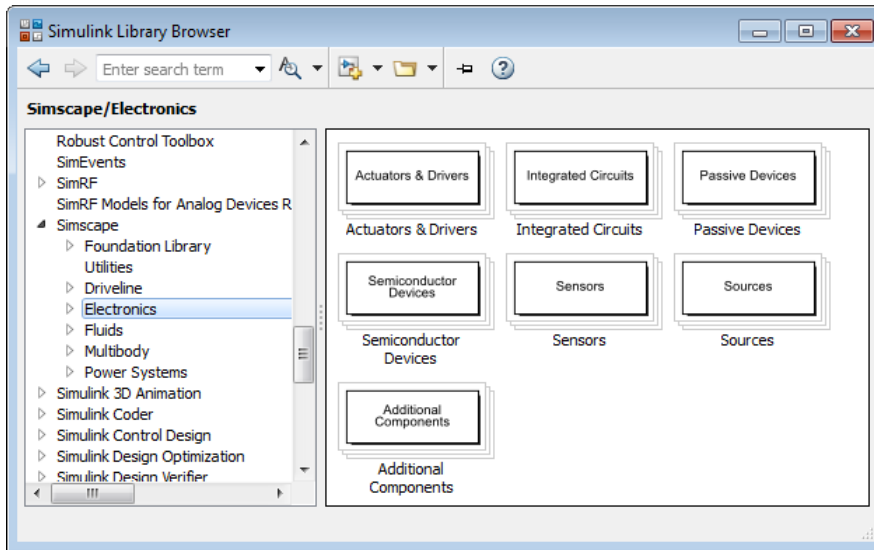
Opening Simscape Electronics Libraries

There are two ways to access Simscape Electronics blocks:

- “Using the Simulink Library Browser to Access the Block Libraries” on page 1-6
- “Using the Command Prompt to Access the Block Libraries” on page 1-7

Using the Simulink Library Browser to Access the Block Libraries

You can access the blocks through the Simulink Library Browser. To display the Library Browser, type `slLibraryBrowser` in the MATLAB Command Window. Then expand the **Simscape** entry in the contents tree.

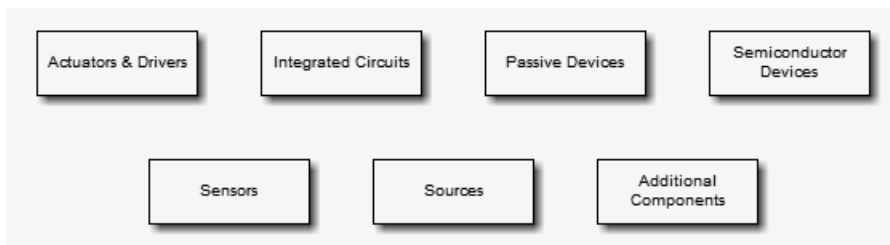


Using the Command Prompt to Access the Block Libraries

Another way to access the block libraries is to open them individually by using the command prompt:

- To open just the Simscape Electronics library, type `elec_lib` in the MATLAB Command Window.
- To open the Simscape library (to access the utility blocks, as well as electrical sources, sensors, and other Foundation library blocks), type `simscape` in the MATLAB Command Window.
- To open the main Simulink library (to access generic Simulink blocks), type `sllibraryBrowser` in the MATLAB Command Window.

The Simscape Electronics library window is shown in the following figure. Each icon in the window represents a library. Some of these libraries contain second-level sublibraries. Double-click an icon to open the corresponding library.



Modeling Electronic and Electromechanical Systems

When you model and analyze an electronic or electromechanical system using Simscape Electronics software, your workflow might include the following tasks:

- 1** Create a Simulink model that includes electronic or electromechanical components.

In the majority of applications, it is most natural to model the physical system using Simscape and Simscape Electronics blocks, and then develop the controller or signal processing algorithm in Simulink.

For more information about modeling the physical system, see “Essential Electronic Modeling Techniques” on page 1-10.

- 2** Define component data by specifying electrical or mechanical properties as defined on a datasheet.

For more information about parameterizing blocks, see “Parameterizing Blocks from Datasheets” on page 2-2.

- 3** Configure the solver options.

For more information about the settings that most affect the solution of a physical system, see “Setting Up Solvers for Physical Models” (Simscape).

- 4** Run the simulation.

For more information on how to perform time-domain simulation of an electronic system, see “Simulating an Electronic System” on page 1-14.



Essential Electronic Modeling Techniques

In this section...
“Overview of Modeling Rules” on page 1-10
“Required Blocks” on page 1-11
“Creating a New Model” on page 1-12
“Modeling Instantaneous Events” on page 1-12
“Using Simulink Blocks to Model Physical Components” on page 1-12

Overview of Modeling Rules

Simscape Electronics models are essentially Simscape block diagrams. To build a system-level model with electrical blocks, use a combination of Simscape Electronics blocks and other Simscape and Simulink blocks. You can connect Simscape Electronics blocks directly to Simscape blocks. You can connect Simulink blocks through the Simulink-PS Converter and PS-Simulink Converter blocks from the Simscape Utilities library. These blocks convert electrical signals to and from Simulink mathematical signals.

The rules that you must follow when building an electronic or electromechanical model are described in “Basic Principles of Modeling Physical Networks” (Simscape). This section briefly reviews these rules.

- Simscape Electronics blocks, in general, feature Conserving ports  and Physical Signal inports and outports .
- There are two main types of Physical Conserving ports used in Simscape Electronics blocks: electrical and mechanical rotational. Each type has specific Through and Across variables associated with it.
- You can connect Conserving ports only to other Conserving ports of the same type.
- The Physical connection lines that connect Conserving ports together are nondirectional lines that carry physical variables (Across and Through variables, as described above) rather than signals. You cannot connect Physical lines to Simulink ports or to Physical Signal ports.
- Two directly connected Conserving ports must have the same values for all their Across variables (such as voltage or angular velocity).
- You can branch Physical connection lines. When you do so, components directly connected with one another continue to share the same Across variables. Any Through

variable (such as current or torque) transferred along the Physical connection line is divided among the multiple components connected by the branches. How the Through variable is divided is determined by the system dynamics.

For each Through variable, the sum of all its values flowing into a branch point equals the sum of all its values flowing out.

- You can connect Physical Signal ports to other Physical Signal ports with regular connection lines, similar to Simulink signal connections. These connection lines carry physical signals between Simscape Electronics blocks.
- You can connect Physical Signal ports to Simulink ports through special converter blocks. Use the Simulink-PS Converter block to connect Simulink outputs to Physical Signal inputs. Use the PS-Simulink Converter block to connect Physical Signal outputs to Simulink inputs.
- Physical Signals can have units associated with them. Simscape Electronics block dialogs let you specify the units along with the parameter values, where appropriate. Use the converter blocks to associate units with an input signal and to specify the desired output signal units.

For examples of applying these rules when creating an actual electromechanical model, see “DC Motor Model” on page 1-17.

MathWorks recommends that you build, simulate, and test your model incrementally. Start with an idealized, simplified model of your system, simulate it, verify that it works the way you expected. Then incrementally make your model more realistic, factoring in effects such as motor shaft compliance, hard stops, and the other things that describe real-world phenomena. Simulate and test your model at every incremental step. Use subsystems to capture the model hierarchy, and simulate and test your subsystems separately before testing the whole model configuration. This approach helps you keep your models well organized and makes it easier to troubleshoot them.

Required Blocks

Each topologically distinct physical network in a diagram requires exactly one Solver Configuration block, found in the Simscape Utilities library. The Solver Configuration block specifies global environment information for simulation and provides parameters for the solver that your model needs before you can begin simulation. For more information, see the Solver Configuration block reference page.

Each electrical network requires an Electrical Reference block. This block establishes the electrical ground for the circuit. Networks with electromechanical blocks also require a

Mechanical Rotational Reference block. For more information about using reference blocks, see “Grounding Rules” (Simscape).

Creating a New Model

An easy way to start a new Simscape Electronics model, prepopulated with the required blocks, is to use the Simscape function `ssc_new` with a domain type of `electrical`. For more information, see “Creating a New Simscape Model” (Simscape).

You can also use the Creating A New Circuit example (under Simscape examples) as a template for a new model. This example opens a simple electrical model, prepopulated with some useful blocks, and also opens an Electrical Starter Palette, which contains links to the most often used electrical components. Open the example by typing `ssc_new_elec` in the MATLAB Command Window and use **File > Save As** to save the example model under the desired name. Then delete the unwanted blocks and add new ones from the Electrical Starter Palette and from the block libraries.

Modeling Instantaneous Events

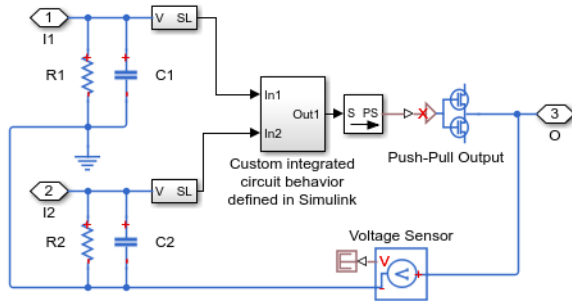
When working with Simscape Electronics software, your model may include Simulink blocks that create instantaneous changes to the physical system inputs through the Simulink-PS Converter block, such as those associated with events or discrete sampling. When you build this type of model, make sure the corresponding zero crossings are generated.

Many blocks in the Simulink library generate these zero crossings by default. For example, the Pulse Generator block produces a discrete-time output by default, and generates the corresponding zero crossings. To model instantaneous events, select **Use local settings** or **Enable all** for the **Zero crossing control** option under the model’s Solver Configuration Parameters to generate zero crossings. For more information about zero crossing control, see “Zero-crossing control” (Simulink).

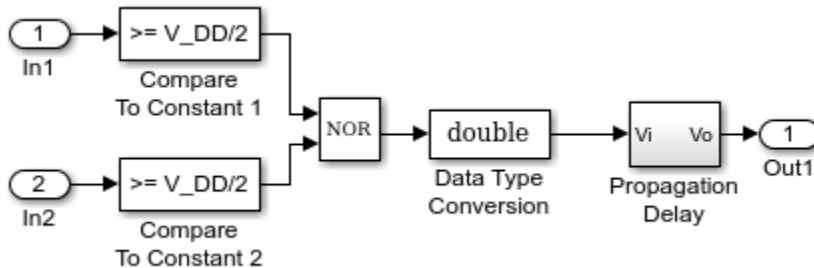
Using Simulink Blocks to Model Physical Components

To run a fast simulation that approximates the behavior of the physical components in a system, you may want to use Simulink blocks to model of one or more physical components.

The Modeling an Integrated Circuit example uses Simulink to model a physical component. The 2-Input NOR (Behavioral Model) masked subsystem is a behavioral model, built using Simscape Foundation Library blocks.



This behavioral model contains a subsystem comprised of Simulink blocks, which implements the custom integrated circuit behavior.



The Simulink Logical Operator block implements the behavioral model of the two-input NOR gate. Using Simulink in this manner introduces algebraic loops, unless you place a lag somewhere between the physical signal inputs and outputs. In this case, a first-order lag is included in the Propagation Delay subsystem to represent the delay due to gate capacitances. For applications where no lag is required, use blocks from the Physical Signals sublibrary in the Simscape Foundation Library to implement the desired functionality.

Simulating an Electronic System

In this section...

“Selecting a Solver” on page 1-14

“Specifying Simulation Accuracy/Speed Tradeoff” on page 1-14

“Avoiding Simulation Issues” on page 1-15

“Running a Time-Domain Simulation” on page 1-16

“Running a Small-Signal Frequency-Domain Analysis” on page 1-16

Selecting a Solver

Simscape Electronics software supports all of the continuous-time solvers that Simscape supports. For more information, see “Setting Up Solvers for Physical Models” (Simscape).

You can select any of the supported solvers for running a Simscape Electronics simulation. The variable-step solvers, `ode23t` and `ode15s`, are recommended for most applications because they run faster and work better for systems with a range of both fast and slow dynamics. The `ode23t` solver is closest to the solver that SPICE traditionally uses.

To use Simulink Coder software to generate standalone C or C++ code from your model, you must use the `ode14x` solver. For more information about code generation, see “Code Generation” (Simscape).

Specifying Simulation Accuracy/Speed Tradeoff

To trade off accuracy and simulation time, adjust one or more of the following parameters:

- **Relative tolerance** (in the Configuration Parameters dialog box)
- **Absolute tolerance** (in the Configuration Parameters dialog box)
- **Max step size** (in the Configuration Parameters dialog box)
- **Consistency Tolerance** (in the Solver Configuration block dialog box)

In most cases, the default tolerance values produce accurate results without sacrificing unnecessary simulation time. The parameter value that is most likely to be inappropriate for your simulation is **Max step size**, because the default value, `auto`, depends on the

simulation start and stop times rather than on the amount by which the signals are changing during the simulation. If you are concerned about the solver missing significant behavior, change the parameter to prevent the solver from taking too large a step.

The Simulink documentation describes the following parameters in more detail and provides tips on how to adjust them:

- “Relative tolerance” (Simulink)
- “Absolute tolerance” (Simulink)
- “Max step size” (Simulink)

The Solver Configuration block reference page in the Simscape documentation explains when to adjust the **Consistency Tolerance** parameter value.

Avoiding Simulation Issues

If you experience a simulation issue, first read “Troubleshooting Simulation Errors” (Simscape) to learn about general troubleshooting techniques.

Note Simscape Electronics software does not have the ability to model large circuits with dozens of analog components. If you encounter convergence issues when trying to simulate a model with more than a few tens of transistors, you may find that the limitations of Simscape Electronics software prevent you from achieving convergence with any set of simulation parameter values.

There are a few techniques you can apply to any Simscape Electronics model to overcome simulation issues:

- Add parasitic capacitors and/or resistors (specifically, junction capacitance and ohmic resistance) to the circuit to avoid numerical issues. The Astable Oscillator example uses these devices.
- Adjust the current and voltage sources so they start at zero and ramp up to their final values rather than starting at nonzero values.

“Modeling Instantaneous Events” on page 1-12 and “Using Simulink Blocks to Model Physical Components” on page 1-12 describe how to avoid simulation errors in the presence of specific Simscape Electronics model configurations.

Running a Time-Domain Simulation

When you run a time-domain simulation, Simscape Electronics software uses the Simscape solver to analyze the physical system in the Simulink environment. For more information, see “How Simscape Simulation Works” (Simscape).

Running a Small-Signal Frequency-Domain Analysis

You can perform small-signal analysis for Simscape and Simscape Electronics models using linearization capabilities of Simulink software. For more information, see “Linearize an Electronic Circuit” (Simscape).

DC Motor Model

In this section...

“Overview of DC Motor Example” on page 1-17

“Selecting Blocks to Represent System Components” on page 1-17

“Building the Model” on page 1-18

“Specifying Model Parameters” on page 1-20

“Configuring the Solver Parameters” on page 1-25

“Running the Simulation and Analyzing the Results” on page 1-26

Overview of DC Motor Example

In this example, you model a DC motor driven by a constant input signal that approximates a pulse-width modulated signal and look at the current and rotational motion at the motor output.

To see the completed model, open the PWM-Controlled DC Motor example.

Selecting Blocks to Represent System Components

Select the blocks to represent the input signal, the DC motor, and the motor output displays.

The following table describes the role of the blocks that represent the system components.

Block	Description
Solver Configuration	Defines solver settings that apply to all physical modeling blocks.
DC Voltage Source	Generates a DC signal.
Controlled PWM Voltage	Generates the signal that approximates a pulse-width modulated motor input signal.
H-Bridge	Drives the DC motor.

Block	Description
Current Sensor	Converts the electrical current that drives the motor into a physical signal proportional to the current.
Ideal Rotational Motion Sensor	Converts the rotational motion of the motor into a physical signal proportional to the motion.
DC Motor	Converts input electrical signal into mechanical motion.
PS-Simulink Converter	Converts the input physical signal to a Simulink signal.
Scope	Displays motor current and rotational motion.
Electrical Reference	Provides the electrical ground.
Mechanical Rotational Reference	Provides the mechanical ground.

Building the Model

Create a Simulink model, add blocks to the model, and connect the blocks.

- 1 Create a new model.
- 2 Add to the model the blocks listed in the following table. The Library column of the table specifies the hierarchical path to each block.

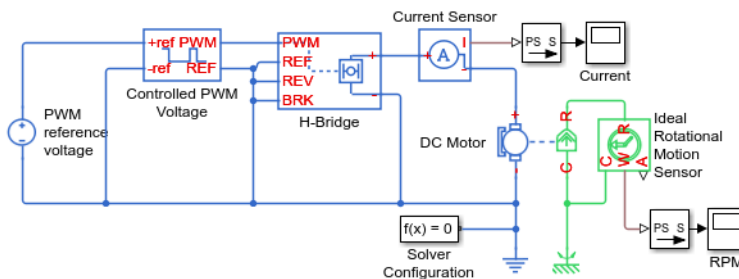
Block	Library Path	Quantity
Solver Configuration	Simscape > Utilities	1
DC Voltage Source	Simscape > Foundation Library > Electrical > Electrical Sources	1
Controlled PWM Voltage	Simscape > Electronics > Actuators & Drivers > Drivers	1
H-Bridge	Simscape > Electronics > Actuators & Drivers > Drivers	1
Current Sensor	Simscape > Foundation Library > Electrical > Electrical Sensors	1
Ideal Rotational Motion Sensor	Simscape > Foundation Library > Mechanical > Mechanical Sensors	1

Block	Library Path	Quantity
DC Motor	Simscape > Electronics > Actuators & Drivers > Rotational Actuators	1
PS-Simulink Converter	Simscape > Utilities	2
Scope	Simulink > Commonly Used Blocks	2
Electrical Reference	Simscape > Foundation Library > Electrical > Electrical Elements	1
Mechanical Rotational Reference	Simscape > Foundation Library > Mechanical > Rotational Elements	1

Note You can use the Simscape function `ssc_new` with a domain type of `electrical` to create a Simscape model that contains the following blocks:

- **Simulink-PS Converter**
- **PS-Simulink Converter**
- **Scope**
- **Solver Configuration**
- **Electrical Reference**

3 Rename and connect the blocks as shown in the diagram.



Now you are ready to specify block parameters.

Specifying Model Parameters

Specify the following parameters to represent the behavior of the system components:

- “Model Setup Parameters” on page 1-20
- “Motor Input Signal Parameters” on page 1-20
- “Motor Parameters” on page 1-23
- “Current Display Parameters” on page 1-24
- “Torque Display Parameters” on page 1-24

Model Setup Parameters

The following blocks specify model information that is not specific to a particular block:

- Solver Configuration
- Electrical Reference
- Mechanical Rotational Reference

As with Simscape models, you must include a Solver Configuration block in each topologically distinct physical network. This example has a single physical network, so use one Solver Configuration block with the default parameter values.

You must include an Electrical Reference block in each Simscape Electronics network. You must include a Mechanical Rotational Reference block in each network that includes electromechanical blocks. These blocks do not have any parameters.

For more information about using reference blocks, see “Grounding Rules” (Simscape).

Motor Input Signal Parameters

You generate the motor input signal using three blocks:

- The DC Voltage Source block (PWM reference voltage) generates a constant signal.
- The Controlled PWM Voltage block generates a pulse-width modulated signal.
- The H-Bridge block drives the motor.

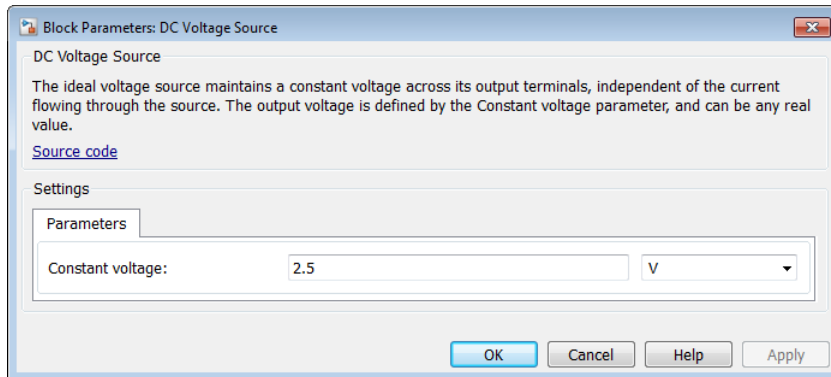
In this example, all input ports of the H-Bridge block except the PWM port are connected to ground. As a result, the H-Bridge block behaves as follows:

- When the motor is on, the H-Bridge block connects the motor terminals to the power supply.
- When the motor is off, the H-Bridge block acts as a freewheeling diode to maintain the motor current.

In this example, you simulate the motor with a constant current whose value is the average value of the PWM signal. By using this type of signal, you set up a fast simulation that estimates the motor behavior.

1 Set the DC Voltage Source block parameters as follows:

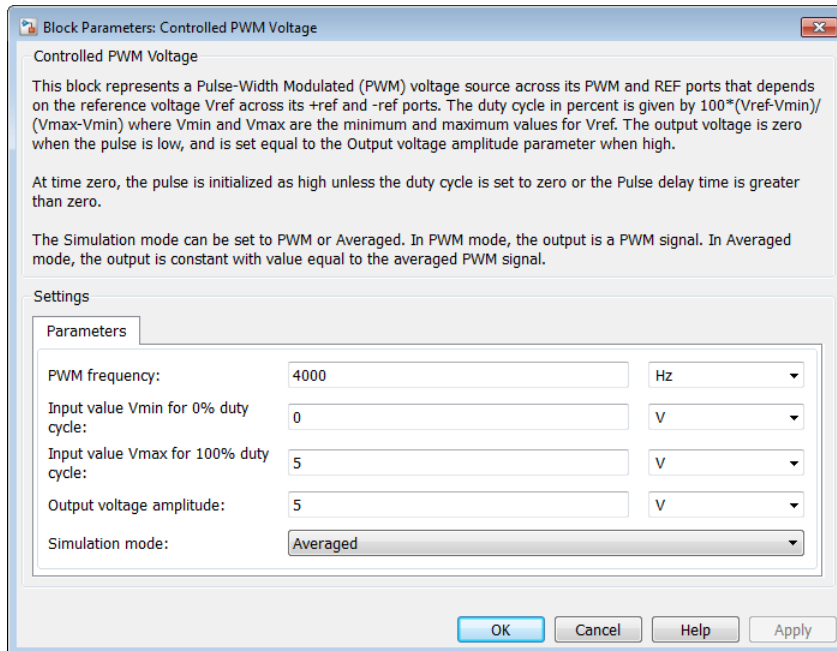
- **Constant voltage** = 2.5



2 Set the Controlled PWM Voltage block parameters as follows:

- **PWM frequency** = 4000
- **Simulation mode** = Averaged

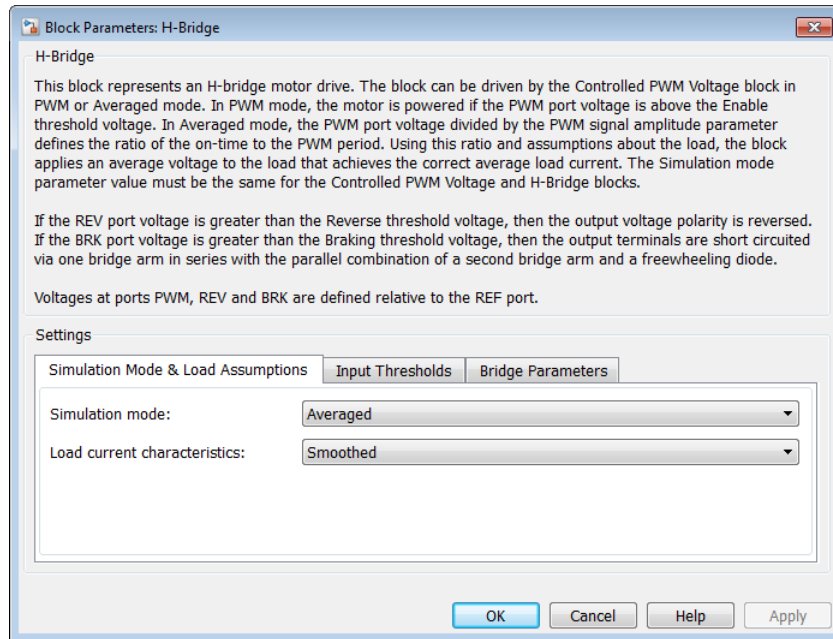
This value tells the block to generate an output signal whose value is the average value of the PWM signal. Simulating the motor with an averaged signal estimates the motor behavior in the presence of a PWM signal. To validate this approximation, use value of PWM for this parameter.



3 Set the H-Bridge block parameters as follows:

- **Simulation mode = Averaged**

This value tells the block to generate an output signal whose value is the average value of the PWM signal. Simulating the motor with an averaged signal estimates the motor behavior in the presence of a PWM signal. To validate this approximation, use value of **PWM** for this parameter.



Motor Parameters

Configure the block that models the motor.

Set the Motor block parameters as follows, leaving the unit settings at their default values where applicable:

- **Electrical Torque** tab:
 - **Model parameterization** = By rated power, rated speed & no-load speed
 - **Armature inductance** = 0.01
 - **No-load speed** = 4000
 - **Rated speed (at rated load)** = 2500
 - **Rated load (mechanical power)** = 10
 - **Rated DC supply voltage** = 12
- **Mechanical** tab:

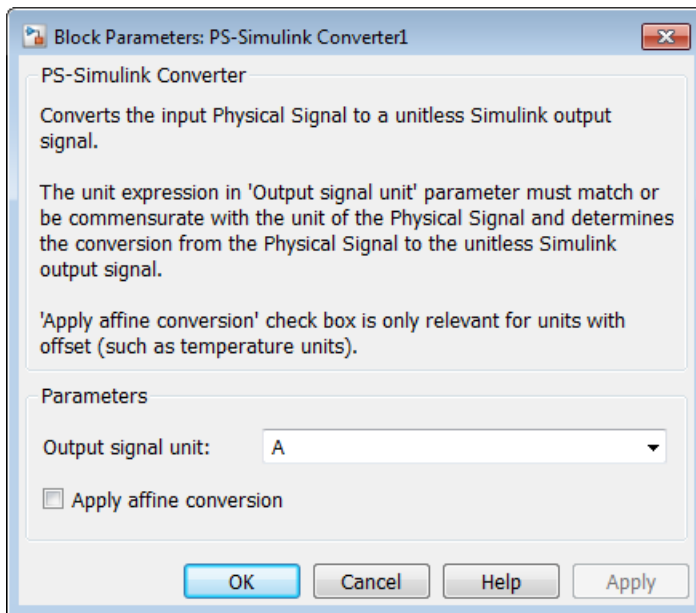
- **Rotor inertia** = 2000
- **Rotor damping** = $1e-06$

Current Display Parameters

Specify the parameters of the blocks that create the motor current display:

- Current Sensor block
- PS-Simulink Converter1 block
- Current scope

Of the three blocks, only the PS-Simulink Converter1 block has parameters. Set the PS-Simulink Converter1 block **Output signal unit** parameter to A to indicate that the block input signal has units of amperes.



Torque Display Parameters

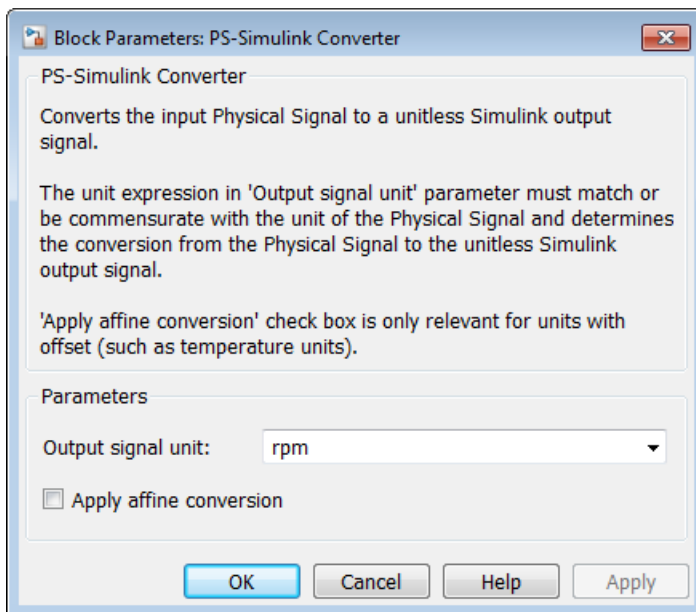
Specify the parameters of the blocks that create the motor torque display:

- Ideal Rotational Motion Sensor block

- PS-Simulink Converter block
- RPM scope

Of the three blocks, only the PS-Simulink Converter block has parameters you need to configure for this example. Set the PS-Simulink Converter block **Output signal unit** parameter to `rpm` to indicate that the block input signal has units of revolutions per minute.

Note You must type this parameter value. It is not available in the drop-down list.



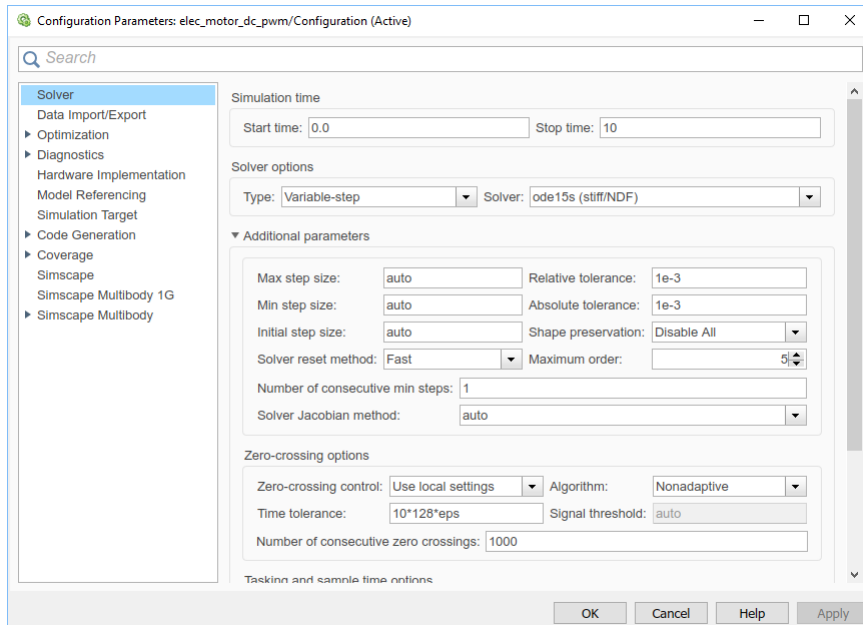
Configuring the Solver Parameters

Configure the solver parameters to use a continuous-time solver because Simscape Electronics models only run with a continuous-time solver. Increase the maximum step size the solver can take so the simulation runs faster.

- 1 In the model window, select **Simulation > Model Configuration Parameters** to open the Configuration Parameters dialog box.

1 Getting Started

- 2 Select ode15s (Stiff/NDF) from the **Solver** list.
- 3 Expand **Additional options** and enter 1 for the **Max step size** parameter value.
- 4 Click **OK**.



For more information about configuring solver parameters, see “Simulating an Electronic System” on page 1-14.

Running the Simulation and Analyzing the Results

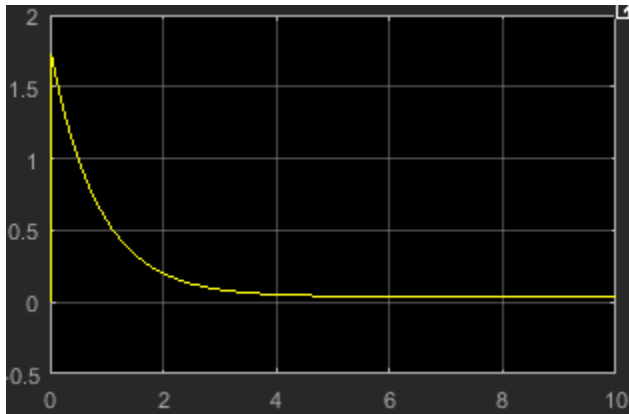
In this part of the example, you run the simulation and plot the results.

In the model window, select **Simulation** > **Run** to run the simulation.

To view the motor current and torque in the Scope windows, double-click the Scope blocks. You can do this before or after you run the simulation.

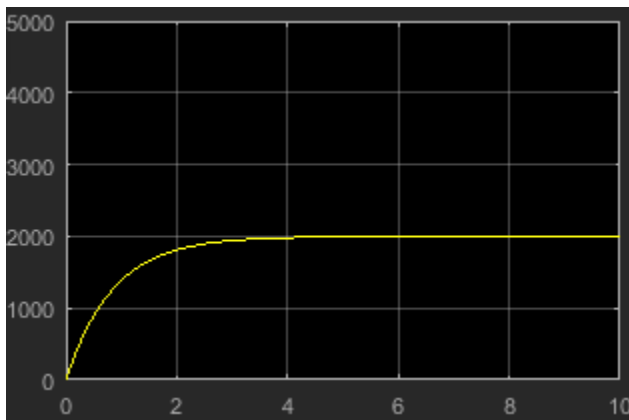
Note By default, the scope displays appear stacked on top of each other on the screen, so you can only see one of them. Click and drag the windows to reposition them.

The following plot shows the motor current.



Motor Current

The next plot shows the motor rpm.



Motor RPM

As expected, the motor runs at about 2000 rpm when the applied DC voltage is 2.5 V.

Triangle Wave Generator Model

In this section...

“Overview of Triangle Wave Generator Example” on page 1-28

“Selecting Blocks to Represent System Components” on page 1-28

“Building the Model” on page 1-30

“Specifying Model Parameters” on page 1-32

“Configuring the Solver Parameters” on page 1-39

“Running the Simulation and Analyzing the Results” on page 1-40

Overview of Triangle Wave Generator Example

In this example, you model a triangle wave generator using Simscape Electronics electrical blocks and custom Simscape Electronics electrical blocks, and then look at the voltage at the wave generator output.

You use a classic circuit configuration consisting of an integrator and a noninverting amplifier to generate the triangle wave, and use datasheets to specify block parameters. For more information, see “Parameterizing Blocks from Datasheets” on page 2-2.

To see the completed model, open the Triangle Wave Generator example.

Selecting Blocks to Represent System Components

First, you select the blocks to represent the input signal, the triangle wave generator, and the output signal display.

You model the triangle wave generator with a set of physical blocks bracketed by a Simulink-PS Converter block and a PS-Simulink Converter block. The wave generator consists of:

- Two operational amplifier blocks
- Resistors and a capacitor that work with the operational amplifiers to create the integrator and noninverting amplifier
- Simulink-PS Converter and PS-Simulink Converter blocks. The function of the Simulink-PS Converter and PS-Simulink Converter blocks is to bridge the physical part

of the model, which uses physical signals, and the rest of the model, which uses Simulink signals.

You have a manufacturer datasheet for the two operational amplifiers you want to model. Later in the example, you use the datasheet to parameterize the Simscape Electronics Band-Limited Op-Amp block.

The following table describes the role of the blocks that represent the system components.

Block	Description
Sine Wave	Generates a sinusoidal signal that controls the resistance of the Variable Resistor block.
Simulink-PS Converter	Converts the sinusoidal Simulink signal to a physical signal.
Solver Configuration	Defines solver settings that apply to all physical modeling blocks.
Electrical Reference	Provides the electrical ground.
Capacitor	Works with an operational amplifier and resistor block to create the integrator.
Resistor	Works with the operational amplifier and capacitor blocks to create the integrator and noninverting amplifier.
Variable Resistor	Supplies a time-varying resistance that adjusts the gain of the integrator, which in turn varies the frequency and amplitude of the generated triangular wave.
DC Voltage Source	Generates a DC reference signal for the operational amplifier block of the noninverting amplifier.
Voltage Sensor	Converts the electrical voltage at the output of the integrator into a physical signal proportional to the current.
PS-Simulink Converter	Converts the output physical signal to a Simulink signal.
Scope	Displays the triangular output wave.
Band-Limited Op-Amp	Works with the capacitor and resistor to create an integrator and a noninverting amplifier.

Block	Description
Diode	Limit the output of the Band-Limited Op-Amp block, to make the output waveform independent of supply voltage.

Building the Model

Create a Simulink model, add blocks to the model, and connect the blocks.

- 1 Create a new model.
- 2 Add to the model the blocks listed in the following table. The Library Path column of the table specifies the hierarchical path to each block.

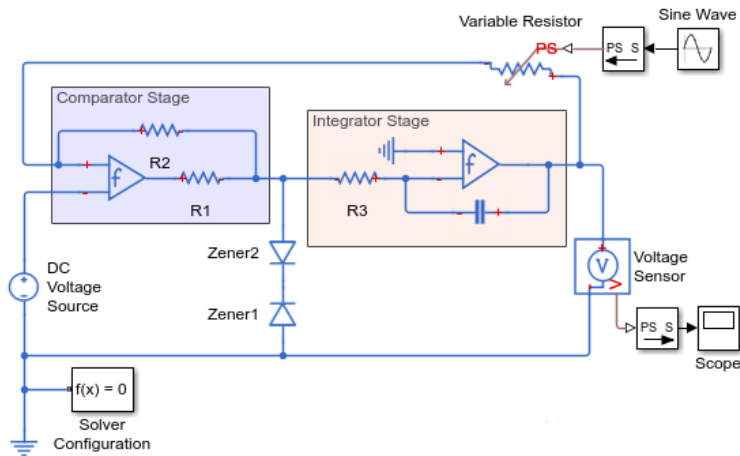
Block	Library Path	Quantity
Sine Wave	Simulink > Sources	1
Simulink-PS Converter	Simscape > Utilities	1
Solver Configuration	Simscape > Utilities	1
Electrical Reference	Simscape > Foundation Library > Electrical > Electrical Elements	1
Capacitor	Simscape > Foundation Library > Electrical > Electrical Elements	1
Resistor	Simscape > Foundation Library > Electrical > Electrical Elements	3
Variable Resistor	Simscape > Foundation Library > Electrical > Electrical Elements	1
DC Voltage Source	Simscape > Foundation Library > Electrical > Electrical Sources	1
Voltage Sensor	Simscape > Foundation Library > Electrical > Electrical Sensors	1
PS-Simulink Converter	Simscape > Utilities	1
Scope	Simulink > Commonly Used Blocks	1

Block	Library Path	Quantity
Band-Limited Op-Amp	Simscape > Electronics > Integrated Circuits	2
Diode	Simscape > Electronics > Semiconductor Devices	2

Note You can use the Simscape function `ssc_new` with a domain type of `electrical` to create a Simscape model that contains the following blocks:

- **Simulink-PS Converter**
- **PS-Simulink Converter**
- **Scope**
- **Solver Configuration**
- **Electrical Reference**

- 3 Rename and connect the blocks as shown in the diagram. The diagram shows that the blocks in the triangle wave generator circuit are organized in two stages. The first stage is a comparator constructed from a Band-Limited Op-Amp block and two Resistor blocks. The second stage is an integrator constructed from a second Band-Limited Op-Amp block, third Resistor, Capacitor, and Electrical Reference.



Now you are ready to specify block parameters.

Specifying Model Parameters

Specify the following parameters to represent the behavior of the system components:

- “Model Setup Parameters” on page 1-32
- “Input Signal Parameters” on page 1-32
- “Triangle Wave Generator Parameters” on page 1-33
- “Signal Display Parameters” on page 1-39

Model Setup Parameters

The following blocks specify model information that is not specific to a particular block:

- Solver Configuration
- Electrical Reference

As with Simscape models, you must include a Solver Configuration block in each topologically distinct physical network. This example has a single physical network, so use one Solver Configuration block with the default parameter values.

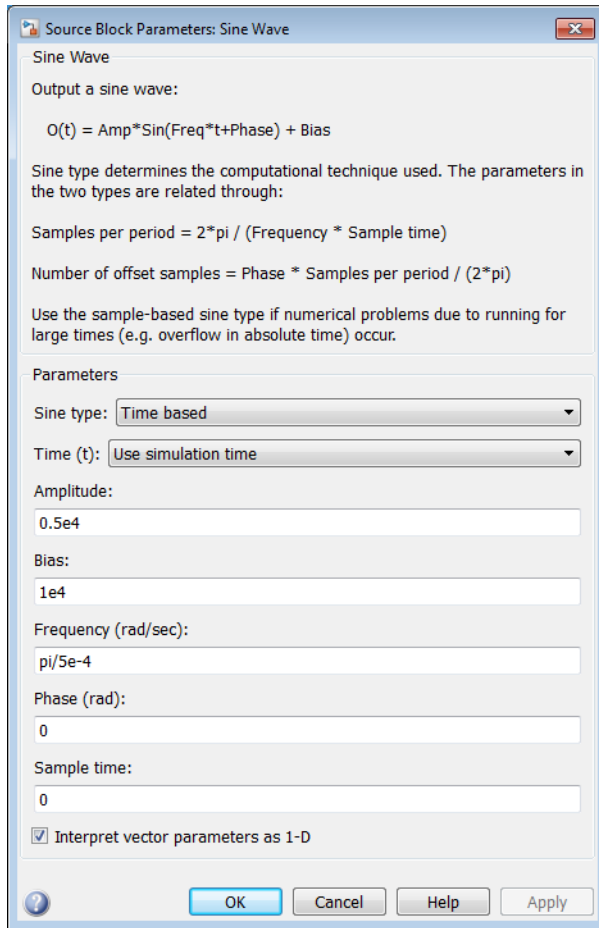
You must include an Electrical Reference block in each Simscape Electronics network. This block does not have any parameters.

Input Signal Parameters

Generate the sinusoidal control signal using the Sine Wave block.

Set the Sine Wave block parameters as follows:

- **Amplitude** = $0.5e4$
- **Bias** = $1e4$
- **Frequency** = $\pi/5e-4$

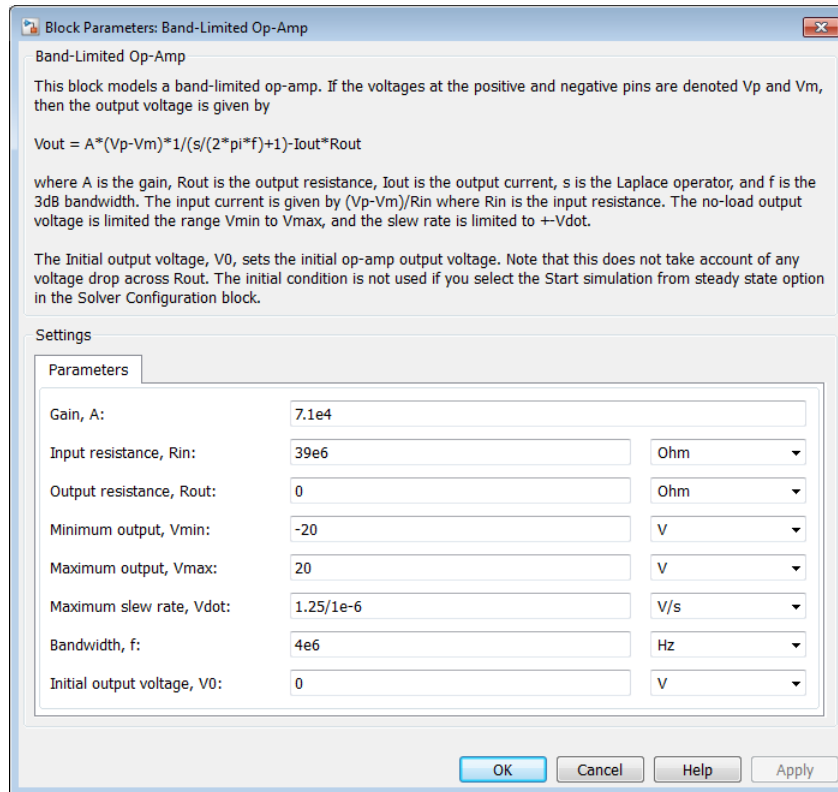


Triangle Wave Generator Parameters

Configure the blocks that model the physical system that generates the triangle wave:

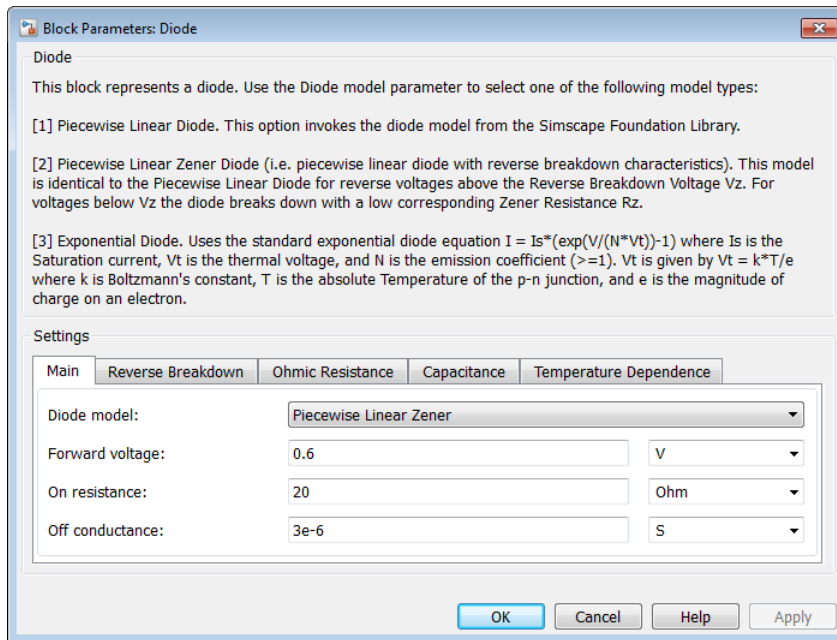
- Integrator stage — Band-Limited Op-Amp, Capacitor, and Resistor block R3
- Comparator stage — Band-Limited Op-Amp1, Resistor blocks R1 and R2
- Variable Resistor
- Diode and Diode1

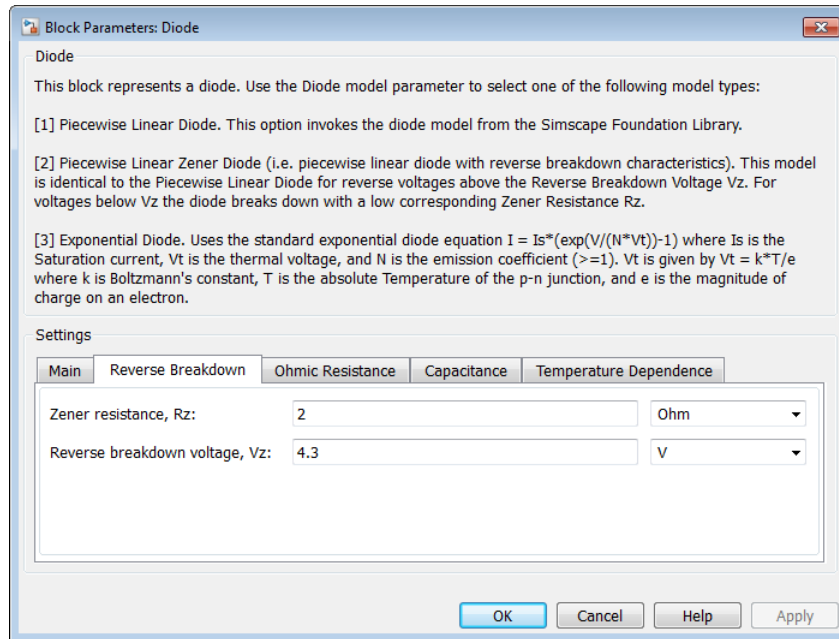
- Simulink-PS Converter and PS-Simulink Converter blocks that bridge the physical part of the model and the Simulink part of the model.
- 1 Accept the default parameters for the Simulink-PS Converter block. These parameters establish the units of the physical signal at the block output such that they match the expected default units of the Variable Resistor block input.
 - 2 Set the two Band-Limited Op-Amp block parameters for the LM7301 device with a +-20V power supply:
 - The datasheet gives the gain as 97dB, which is equivalent to $10^{(97/20)}=7.1e4$. Set the **Gain, A** parameter to $71e4$.
 - The datasheet gives input resistance as 39Mohms. Set **Input resistance, Rin** to $39e6$.
 - Set **Output resistance, Rout** to 0 ohms. The datasheet does not quote a value for Rout, but the term is insignificant compared to the output resistor that it drives.
 - Set minimum and maximum output voltages to -20 and +20 volts, respectively.
 - The datasheet gives the maximum slew rate as $1.25V/\mu s$. Set the **Maximum slew rate, Vdot** parameter to $1.25e6$ V/s.



- 3 Set the two Diode block parameters for a 4.3V zener diode. To model a BZX384-B4V3, set block parameters as follows:
- On the Main tab, set **Diode model** to Piecewise Linear Zener. This selects a simplified zener diode model that is more than adequate to test the correct operation of this circuit.
 - Leave the **Forward voltage** as 0.6V — this is a typical value for most diodes.
 - The datasheet gives the forward current as 250mA when the forward voltage is 1V. So that the Diode block matches this, set the **On resistance** to $(1V - 0.6V)/250mA = 1.6$ ohms.
 - The datasheet gives the reverse leakage current as 3 μ A at a reverse voltage of 1V. Therefore, set the **Off conductance** to $3\mu A/1V = 3e-6$ S.
 - The datasheet gives the reverse voltage as 4.3V. On the Reverse Breakdown tab, set the **Reverse breakdown voltage Vz** to 4.3 V.

- Set the **Zener resistance Rz** to a suitably small number. The datasheet quotes the zener voltage for a reverse current of 5mA. For the Diode block to be representative of the real device, the simulated reverse voltage should be close to 4.3V at 5mA. As Rz tends to zero, the reverse breakdown voltage will tend to Vz regardless of current, as the voltage-current gradient becomes infinite. However, for good numerical properties, Rz must not be made too small. If, say, you allow a 0.01V error on the zener voltage at 5mA, then Rz will be $0.01V/5mA = 2 \text{ ohms}$. Set the **Zener resistance Rz** parameter to this value.

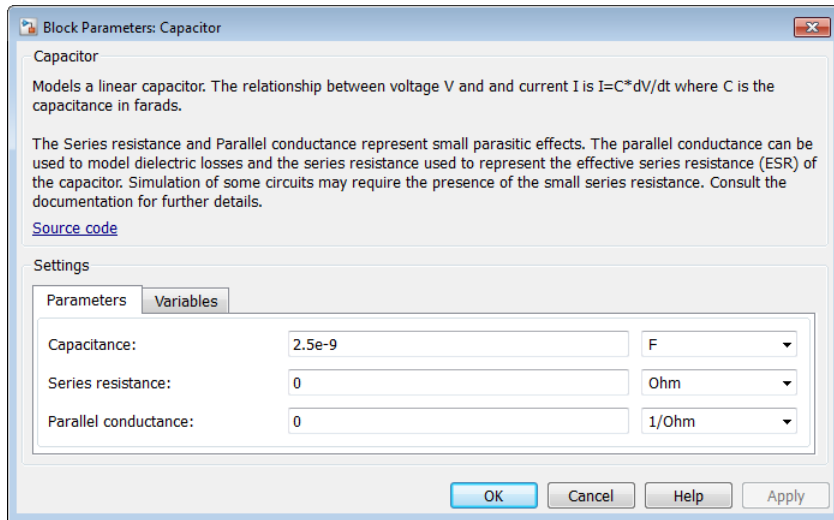




- 4 The Voltage Sensor block does not have any parameters.
- 5 Accept the default parameters for the Variable Resistor block. These parameters establish the units of the physical signal at the block output such that they match the expected default units of the Variable Resistor block input.
- 6 Set the Capacitor block parameters as follows:
 - **Capacitance** = 2.5×10^{-9}
 - **Initial voltage** = 0.08

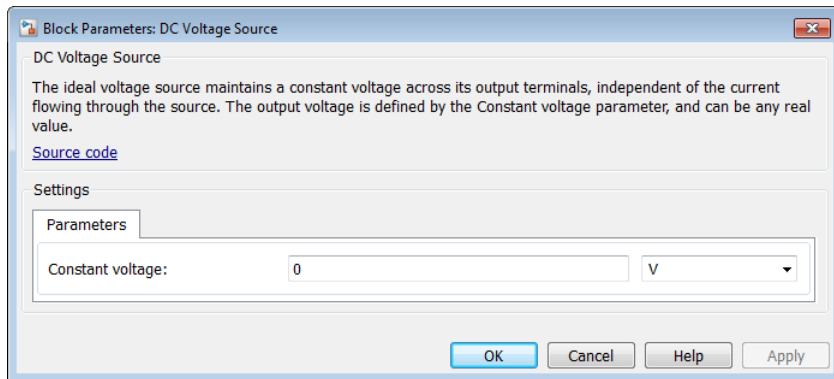
This value starts the oscillation in the feedback loop.

- **Series resistance** = 0



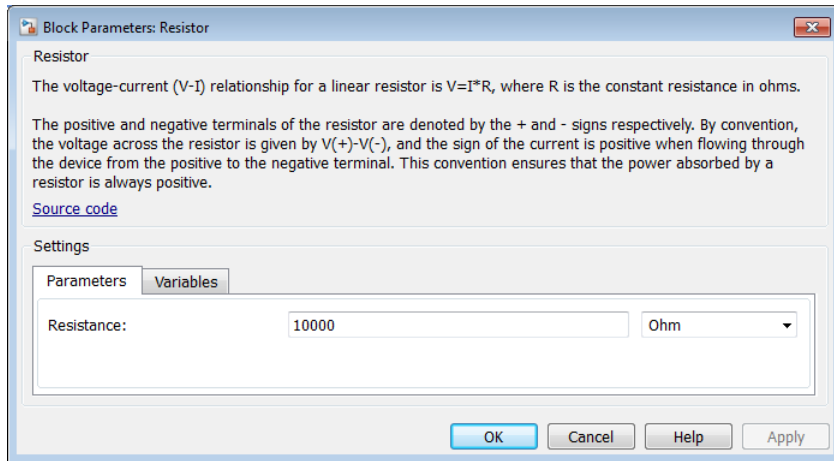
7 Set the DC Voltage Source block parameters as follows:

- **Constant voltage** = 0



8 Set the Resistor R3 block parameters as follows:

- **Resistance** = 10000



- 9 Set the Resistor R1 block parameters as follows:
 - **Resistance** = 1000
- 10 Set the Resistor R2 block parameters as follows:
 - **Resistance** = 10000
- 11 Accept the default parameters for the PS-Simulink Converter block. These parameters establish the units of the physical signal at the block output such that they match the expected default units of the Scope block input.

Signal Display Parameters

Specify the parameters of the Scope block to display the triangular output signal.

Double-click the Scope block and then click the **View > Configuration Properties** to open the Scope Configuration Properties dialog box. On the **Logging** tab, clear the **Limit data points to last** check box.

Configuring the Solver Parameters

Configure the solver parameters to use a continuous-time solver because Simscape Electronics models only run with a continuous-time solver. You also change the simulation end time, tighten the relative tolerance for a more accurate simulation, and remove the limit on the number of simulation data points Simulink saves.

- 1 In the model window, select **Simulation > Model Configuration Parameters** to open the Configuration Parameters dialog box.
- 2 In the **Solver** category in the **Select** tree on the left side of the dialog box:
 - Enter $2000e-6$ for the **Stop time** parameter value.
 - Select `ode23t (Mod. stiff/Trapezoidal)` from the **Solver** list.
 - Enter $4e-5$ for the **Max step size** parameter value.
 - Enter $1e-6$ for the **Relative tolerance** parameter value.
- 3 In the **Data Import/Export** category in the **Select** tree:
 - Clear the **Limit data points to last** check box.
- 4 Click **OK**.

For more information about configuring solver parameters, see “Simulating an Electronic System” on page 1-14.

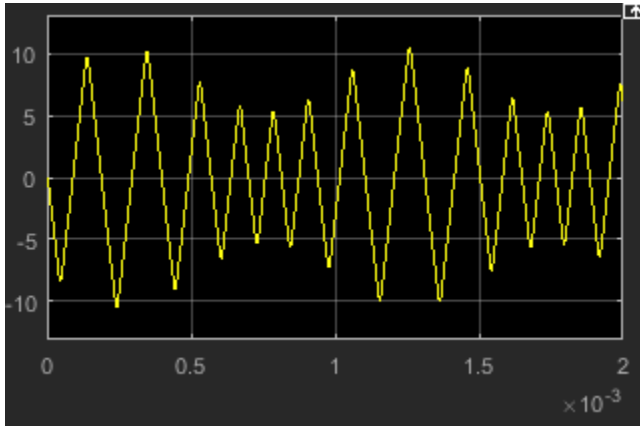
Running the Simulation and Analyzing the Results

Run the simulation and plot the results.

In the model window, select **Simulation > Run** to run the simulation.

To view the triangle wave in the Scope window, double-click the Scope block. You can do this before or after you run the simulation.

The following plot shows the voltage waveform. As the resistance of the Variable Resistor block increases, the amplitude of the output waveform increases and the frequency decreases.



Triangle Waveform Voltage

Modeling an Electronic System

- “Parameterizing Blocks from Datasheets” on page 2-2
- “Parameterize a Piecewise Linear Diode Model” on page 2-4
- “Parameterize an Exponential Diode from a Datasheet” on page 2-8
- “Parameterize an Exponential Diode from SPICE Netlist” on page 2-13
- “Parameterize an Op-Amp from a Datasheet” on page 2-17
- “Additional Parameterization Workflows” on page 2-19
- “Selecting the Output Model for Logic Blocks” on page 2-20
- “Simulating Thermal Effects in Semiconductors” on page 2-24
- “Simulating Thermal Effects in Rotational and Translational Actuators” on page 2-29
- “Plot Basic Characteristics for Semiconductor Blocks” on page 2-32
- “MOSFET Characteristics Viewer” on page 2-35

Parameterizing Blocks from Datasheets

Simscape Electronics software is a system-level simulation tool, which provides blocks with a commensurate level of fidelity. Block parameters are designed, where possible, to match the data found on manufacturer datasheets. For example, the bipolar transistor blocks support parameterization in terms of the small-signal quantities usually quoted on a datasheet, and the underlying model is simpler than that typically used by specialist EDA simulation tools. The smaller number of parameters and simpler underlying models can support MATLAB system performance analysis better, and thereby support design choices. Following system design, you can perform validation in hardware or more detailed modeling and validation using an EDA simulation tool.

The following parameterization examples illustrate various block parameterization techniques:

- Example 1: “Parameterize a Piecewise Linear Diode Model” on page 2-4
- Example 2: “Parameterize an Exponential Diode from a Datasheet” on page 2-8
- Example 3: “Parameterize an Exponential Diode from SPICE Netlist” on page 2-13
- Example 4: “Parameterize an Op-Amp from a Datasheet” on page 2-17

Most of the time, datasheets should be a sufficient source of parameters for Simscape Electronics blocks (see Examples 1 on page 2-4, 2 on page 2-8, and 4 on page 2-17). Sometimes, there is need for more information than is available on the datasheet, and data can be augmented from a manufacturer SPICE netlist. For example, circuit performance may depend on one or two critical components, and increased accuracy is needed either for parameter values or the underlying model. Simscape Electronics libraries contain a SPICE-compatible sublibrary to support this case, and this is illustrated by Example 3 on page 2-13. If you have many components that need to be modeled to a high level of accuracy, then Simulink cosimulation with a specialist circuit simulator may be a better option.

In mechatronic applications in particular, you may need to model input-output behavior of integrated circuits, such as PWM waveform generators and H-bridges. For these two examples, Simscape Electronics libraries contain abstracted-behavior equivalent blocks that you can use. Where you need to model other devices, possible options include creating your own abstracted model using the Simscape language, or using Simulink blocks. For an example of using Simulink blocks, see the Modeling an Integrated Circuit example.

When looking for a datasheet, make sure you have the originating manufacturer datasheet because some resellers abbreviate them.

For additional ways to parameterize and validate your model, see “Additional Parameterization Workflows” on page 2-19.

Parameterize a Piecewise Linear Diode Model

The Triangle Wave Generator example model, also described in “Triangle Wave Generator Model” on page 1-28, contains two zener diodes that regulate the maximum output voltage from an op-amp amplifier circuit. Each of these diodes is implemented with the Simscape Electronics Diode block, parameterized using the **Piecewise Linear Zener** option. This simple model is sufficient to check correct operation of the circuit, and requires fewer parameters than the **Exponential** option of the Diode block. However, when specifying the parameters, you need to take into account the bias condition that will be used in the circuit. This example explains how to do this.

The Phillips Semiconductors datasheet for a BZX384-B4V3 gives the following data:

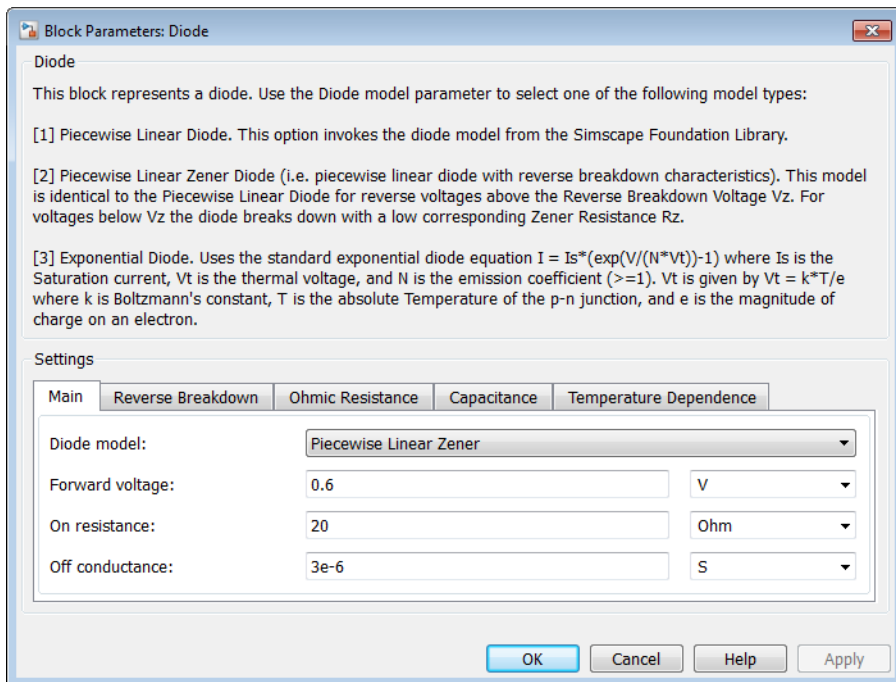
Working voltage, V_Z (V) at $I_{Ztest} = 5$ mA	4.3
Diode capacitance, C_d (pF)	450
Reverse current, I_R (μ A) at $V_R = 1$ V	3
Forward voltage, V_F (V) at $I_F = 5$ mA	0.7

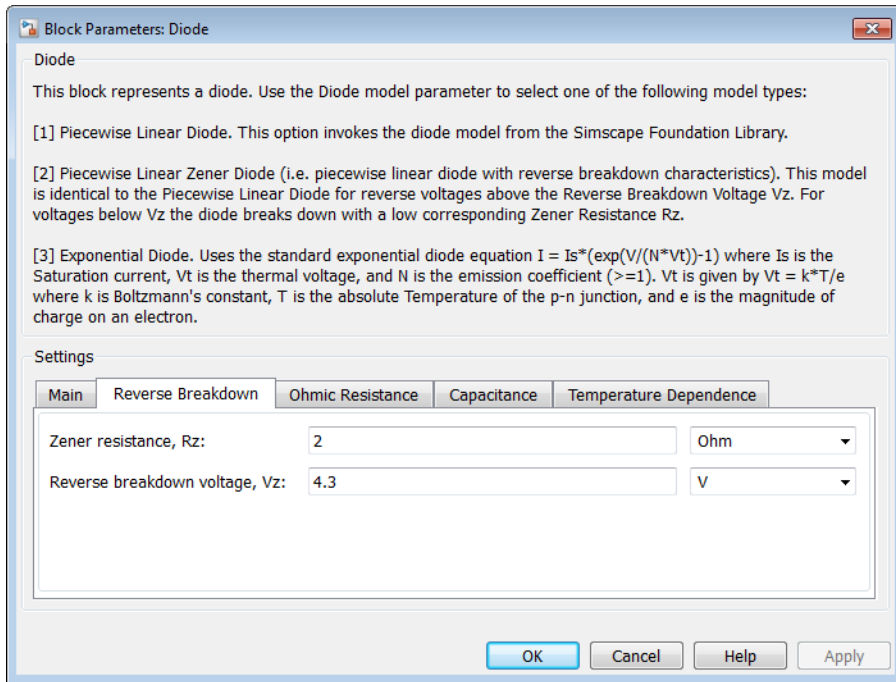
In the datasheet, the tabulated values for V_F are for higher forward currents. This value of 0.7V at 5mA is extracted from the datasheet current-voltage curve, and is chosen as it matches the zener current used when quoting the working voltage of 4.3V.

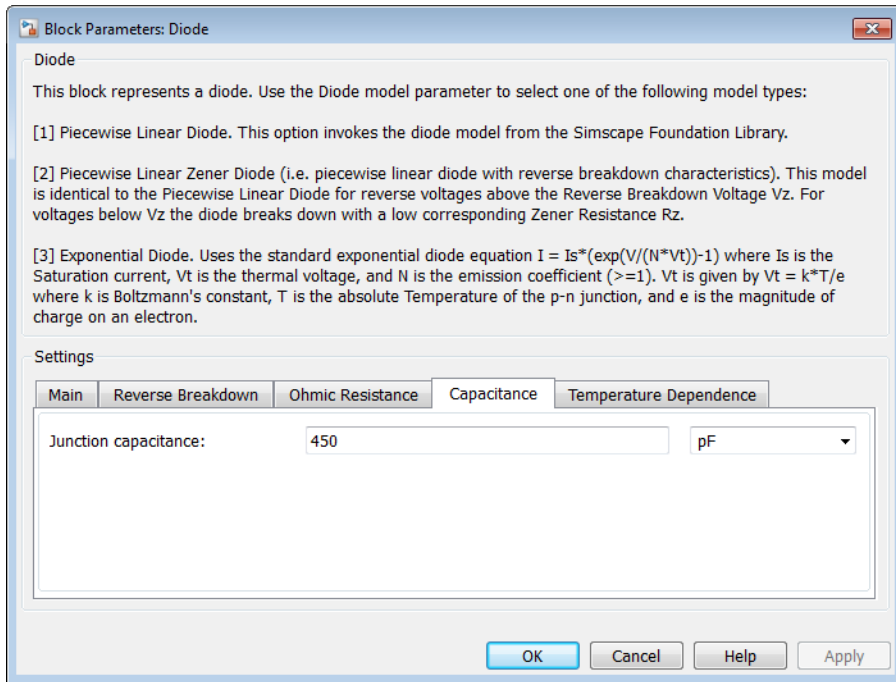
To match the datasheet values, the example sets the piecewise linear zener diode block parameters as follows:

- **Forward voltage.** Leave as default value of 0.6V. This is a typical value for most diodes, and the exact value is not critical. However, it is important that the value set is taken into account when calculating the **On resistance** parameter.
- **On resistance.** This is set using the datasheet information that the forward voltage is 0.7V when the current is 5mA. The voltage to be dropped by the **On resistance** parameter is 0.7V minus the **Forward voltage** parameter, that is 0.1V. Hence the **On resistance** is $0.1V / 5mA = 20 \Omega$.
- **Off conductance.** This is set using the datasheet information on reverse current. The reverse current is $3\mu A$ for a reverse voltage of 1V. Hence the **Off conductance** should be set to $3\mu A / 1V = 3e-6$ S.
- **Reverse breakdown voltage V_z .** This parameter should be set to the datasheet working voltage parameter, 4.3V.

- **Zener resistance R_z .** This needs to be set to a suitable small number. Too small, and the voltage-current relationship becomes very steep, and simulation convergence may not be as efficient. Too large, and the zener voltage will be incorrect. For the Diode block to be representative of the real device, the simulated reverse voltage should be close to 4.3V at 5mA (the reverse bias current provided by the circuit). Allowing a 0.01 V error on the zener voltage at 5mA, R_z will be $0.01V / 5mA = 2 \Omega$.
- **Junction capacitance.** This parameter is set to the datasheet diode capacitance value, 450 pF.







Parameterize an Exponential Diode from a Datasheet

Example 1 on page 2-4 uses a piecewise linear approximation to the diode's exponential current-voltage relationship. This results in more efficient simulation, but requires some thought to go into the setting of block parameter values. An alternative is to use a more complex model that is valid for a wider range of voltage and current values. This example uses the Exponential parameterization option of the Diode block.

This model either requires two data points from the diode current-voltage relationship, or values for the underlying equation coefficients, namely the saturation current I_S and the emission coefficient N . The BZX384-B4V3 datasheet only provides values for the former case. Some datasheets do not give the necessary data for either case, and you must follow the processes in Example 1 on page 2-4 or Example 3 on page 2-13 instead.

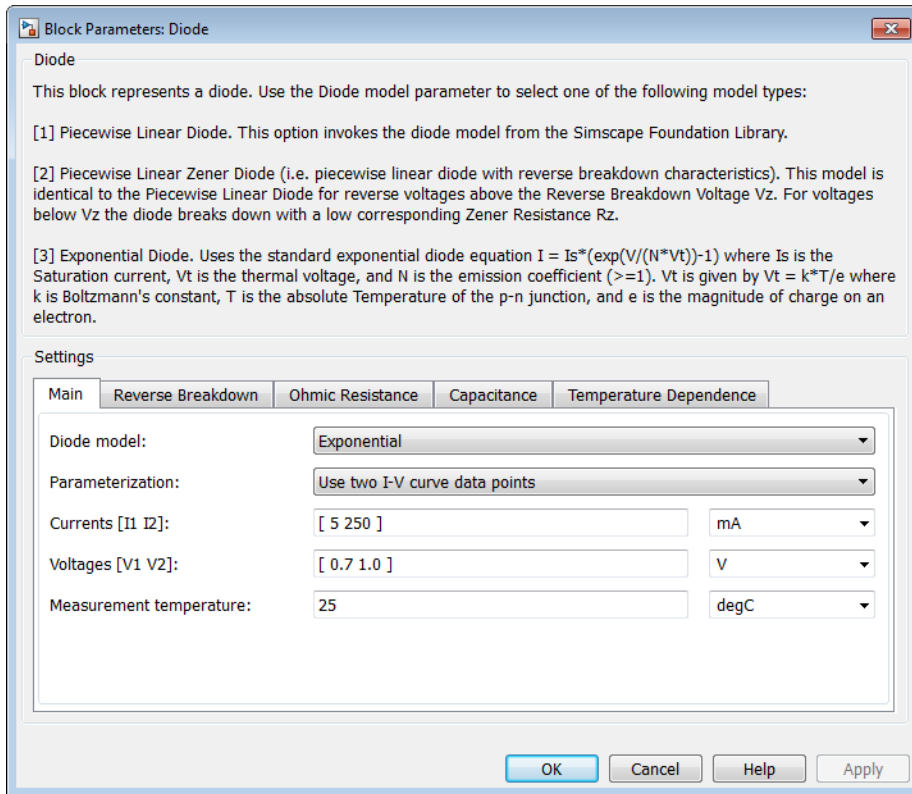
The two data points in the table below are from the BZX384-B4V3 datasheet current-voltage curve:

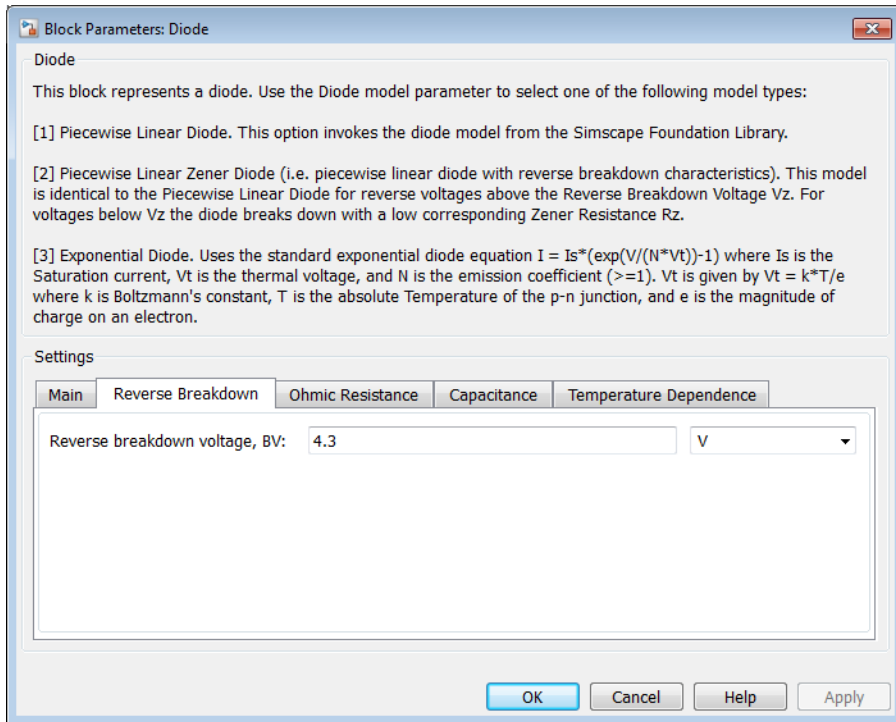
Diode forward voltage, V_F	0.7V	1V
Diode forward current, I_F	5mA	250mA

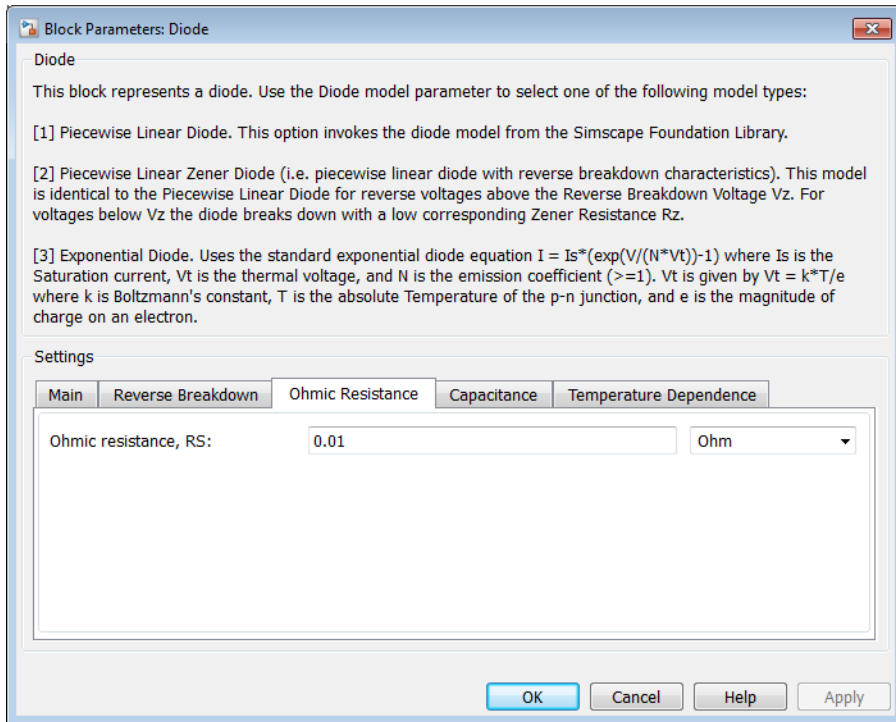
Set the exponential diode block parameters as follows:

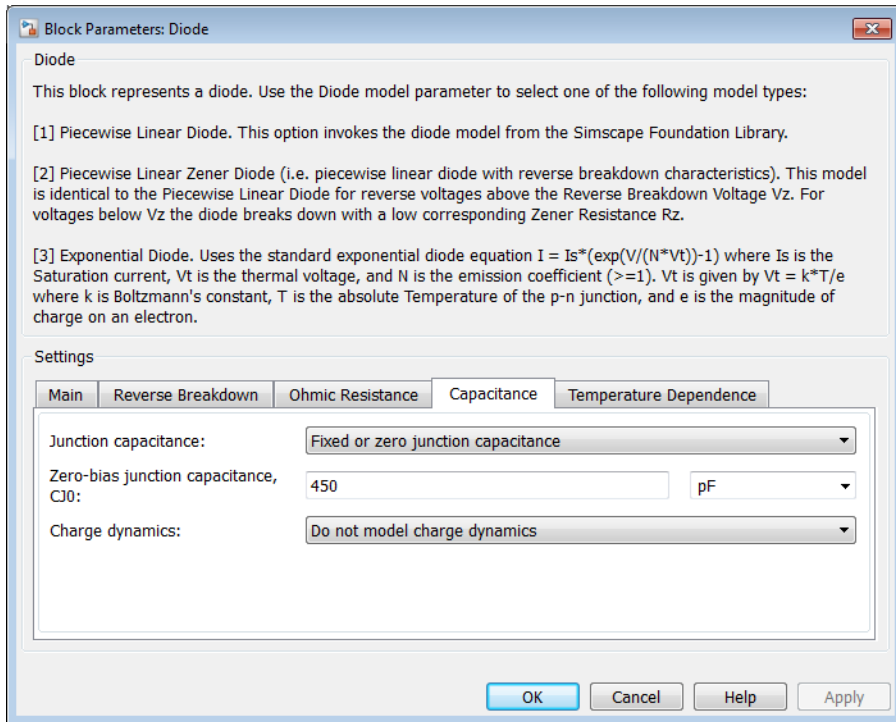
- **Currents [I1 I2]**. Set to [5 250] mA.
- **Voltages [V1 V2]**. Set to [0.7 1.0] V.
- **Reverse breakdown voltage BV**. Set to the datasheet working voltage value, 4.3V.
- **Ohmic resistance**. Leave at its default value of 0.01 Ω . This is an example of a parameter that cannot be determined from the datasheet. However, setting its value to zero is not necessarily a good idea, because a small value can help simulation convergence for some circuit topologies. The default value has negligible effect at the working current of 5mA, the additional voltage drop being $5e-3$ times $0.01 = 5e-5$ V. Physically, this term will not be zero because of the connection resistances.
- **Zero-bias junction capacitance CJO**. Set to the datasheet diode capacitance value, 450 pF.

A more complex capacitance model is also available for the Diode component with the exponential equation option. However, the datasheet does not provide the necessary data. Moreover, the operation of this circuit is not sufficiently sensitive to voltage-dependent capacitance effects to warrant the extra detail.









Parameterize an Exponential Diode from SPICE Netlist

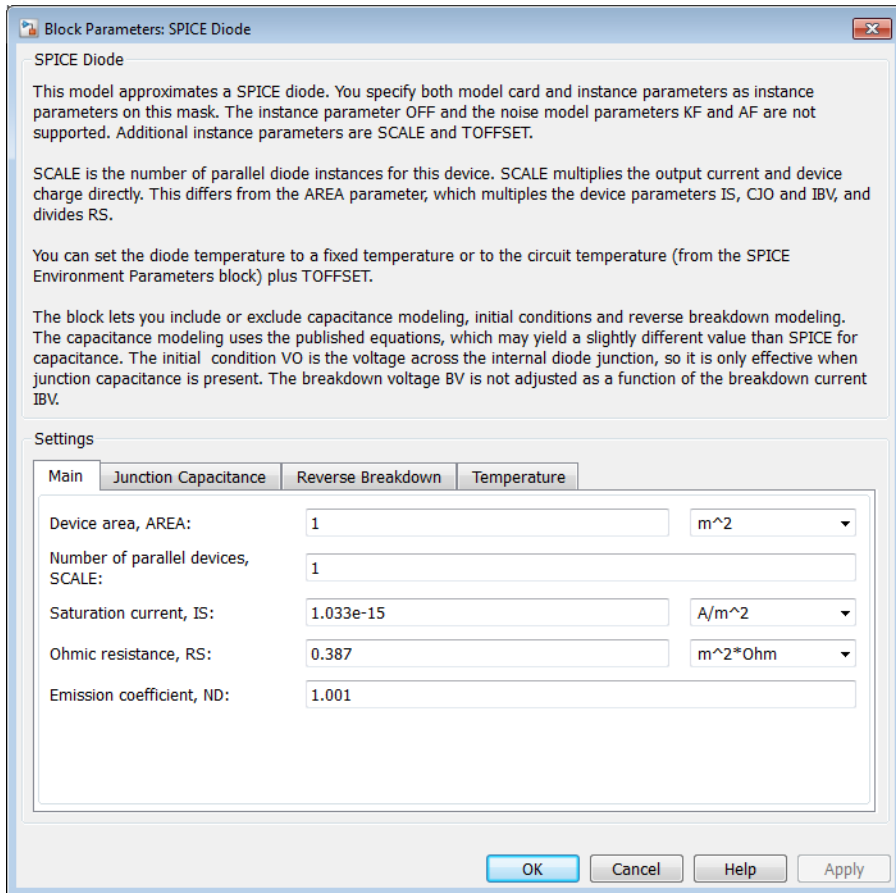
If a datasheet does not provide all of the data required by the component model, another source is a SPICE netlist for the component. Components are defined by a particular type of SPICE netlist called a subcircuit. The subcircuit defines the coefficients for the defining equations. Most component manufacturers make subcircuits available on their websites. The format is ASCII, and you can directly read off the parameters. The BZX384-B4V3 subcircuit can be obtained from Philips Semiconductors <http://www.nxp.com>.

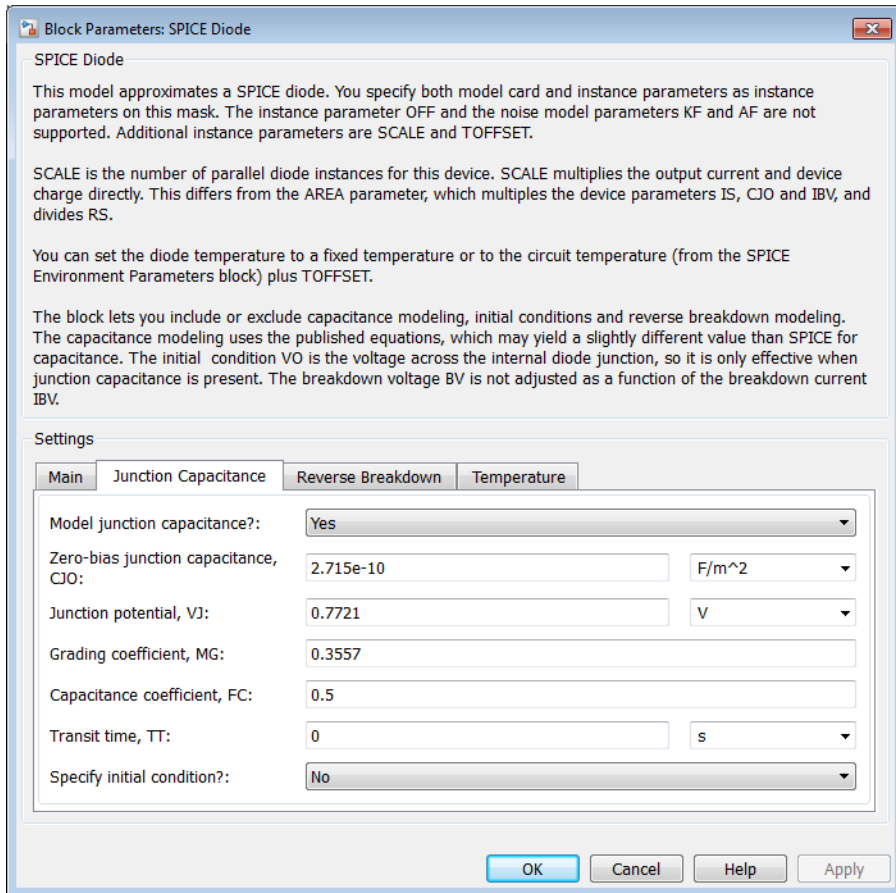
The subcircuit data can be used to parameterize the Simscape Electronics Diode block either in conjunction with the datasheet, or on its own. For example, the Ohmic resistance is defined in the subcircuit as $RS = 0.387$, thus providing the missing piece of information in Example 2 on page 2-8.

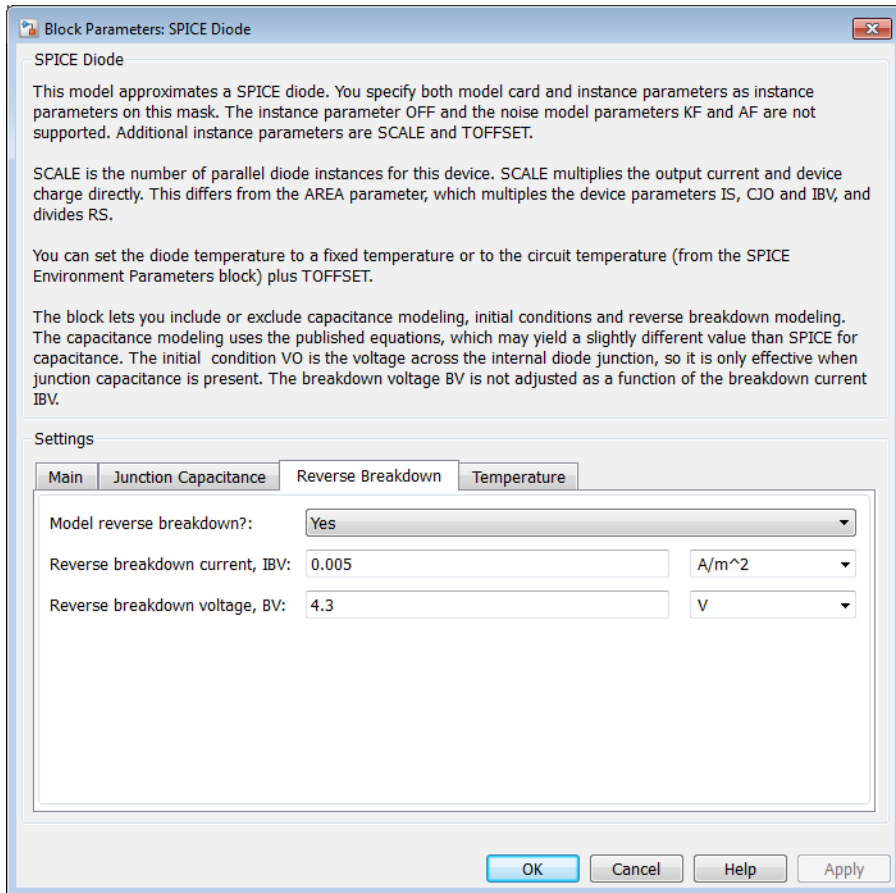
An alternative workflow is to use the Simscape Electronics Additional Components/SPICE-Compatible Components sublibrary. The SPICE Diode block in this sublibrary can be directly parameterized from the subcircuit by setting:

- **Saturation current, IS** to 1.033e-15
- **Ohmic resistance, RS** to 0.387
- **Emission coefficient, ND** to 1.001
- **Zero-bias junction capacitance, CJO** to 2.715e-10
- **Junction potential, VJ** to 0.7721
- **Grading coefficient, MG** to 0.3557
- **Capacitance coefficient, FC** to 0.5
- **Reverse breakdown current, IBV** to 0.005
- **Reverse breakdown voltage, BV** to 4.3

Note that where there is a one-to-one correspondence between subcircuit parameters and datasheet values, the numbers often differ. One reason for this is that datasheet values are sometimes given for maximum values, whereas subcircuit values are normally for nominal values. In this example, the CJO value of 271.5 pF differs from the datasheet capacitance of 450 pF at zero bias for this reason.







Parameterize an Op-Amp from a Datasheet

The Triangle Wave Generator example model, also described in “Triangle Wave Generator Model” on page 1-28, contains two op-amps, parameterized based on a datasheet for an LM7301. The National Semiconductor datasheet gives the following data for this device:

Gain	97dB = 7.1e4
Input resistance	39M Ω
Slew rate	1.25V/ μ s
Bandwidth	4MHz

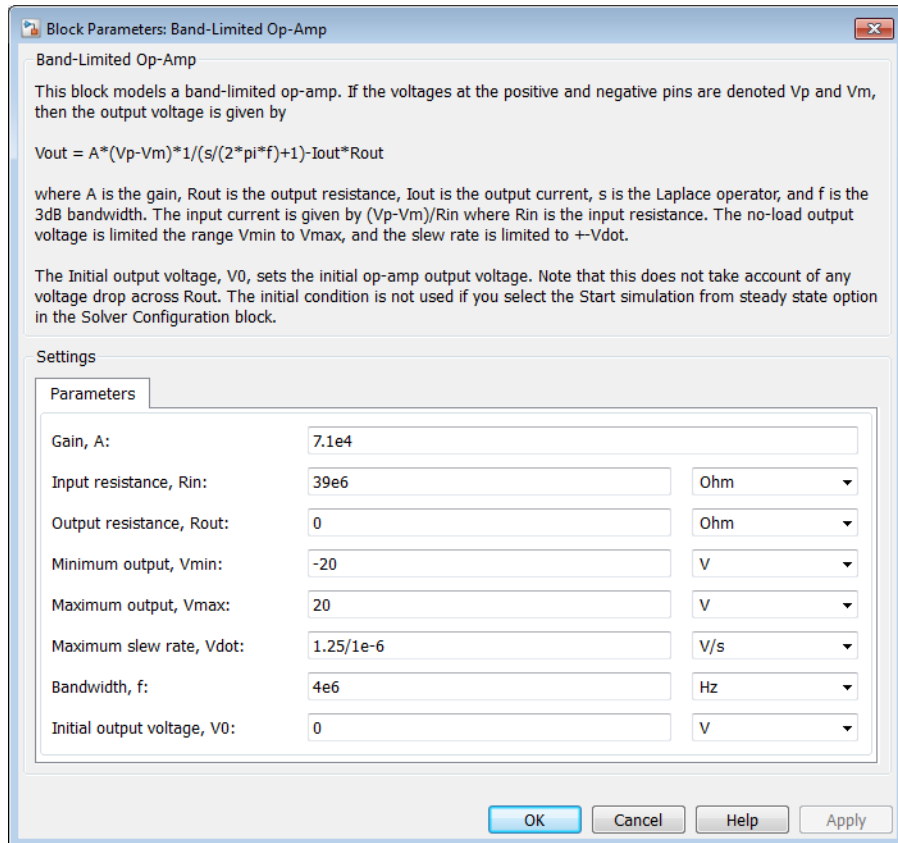
The Band-Limited Op-Amp and Finite-Gain Op-Amp blocks have been designed to work from manufacturer datasheets. Implementing detailed op-amp device models, derived from manufacturer SPICE netlist models, is not recommended, because it provides more accuracy than is typically warranted and slows down simulations. The simple parameterization of the Simscape Electronics op-amp blocks allows you to determine the sensitivity of your circuit to abstracted performance values, such as maximum slew rate and bandwidth. Because of this behavior-based parameterization, you can determine which specification of op-amp is required for a given application. A circuit designer can later match these behavioral parameters, determined from the model, against specific op-amp devices.

Based on the datasheet values above, set the Band-Limited Op-Amp block parameters as follows:

- **Gain** set to 7.1e4
- **Input resistance, Rin** set to 39e6 Ω
- **Output resistance, Rout** set to zero. The value is not defined, but will be small compared to the 1000 Ω load seen by the op-amp.
- **Minimum output, Vmin** set to the negative supply voltage, -20V in this model
- **Maximum output, Vmax** set to the positive supply voltage, 20V in this model
- **Maximum slew rate, Vdot** set to 1.25/1e-6 V/s
- **Bandwidth, f** set to 4e6 Hz

Note that these parameters correspond to the values for +-5 volt operation. The datasheet also gives values for +-2.2V and +-30V operation. It is usually better to pick values for a supply voltage below what your circuit uses, because performance is worse at

lower voltages; for example, the gain is less, and the input impedance is less. You can use the variation in op-amp parameters with supply voltage to suggest a typical range of parameter values for which you should check the operation of your circuit.



Additional Parameterization Workflows

In this section...
“Validation Using Data from SPICE Tool” on page 2-19
“Parameter Tuning Against External Data” on page 2-19
“Building an Equivalent Model of a SPICE Netlist” on page 2-19

Validation Using Data from SPICE Tool

You can validate a parameterized Simscape Electronics component by comparing its behavior to the data from a specialist circuit simulation tool that uses a manufacturer SPICE netlist. Make sure to create a test harness for the component that validates the data across relevant operating points and frequencies.

Parameter Tuning Against External Data

If you have lab measurements of the device, or data from another simulation environment, you can use this to tune the parameters of the equivalent Simscape Electronics component. For an example of parameter tuning, see the example Solar Cell Parameter Extraction From Data.

Building an Equivalent Model of a SPICE Netlist

In Example 3 on page 2-13, parameterization from a SPICE netlist is relatively straightforward because the netlist defines a single device (the diode) plus the corresponding model card (the parameters). Conversely, a netlist for an op-amp may have more than ten devices, plus supporting model cards. In principle, it is possible to build your own equivalent model of a more complex device by using the SPICE-Compatible Components sublibrary. Connect the components together using the information in the netlist. Before embarking on this, make sure that the SPICE-Compatible Components sublibrary has all the component models you need.

If the device models you wish to model are complex (hundreds of components), then cosimulation with an external circuit simulator may be a better approach.

Selecting the Output Model for Logic Blocks

In this section...

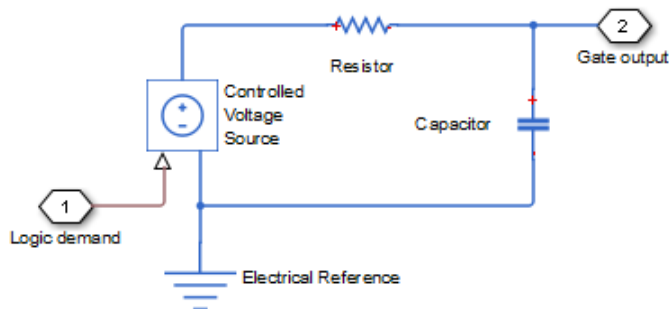
“Available Output Models” on page 2-20

“Quadratic Model Output and Parameters” on page 2-21

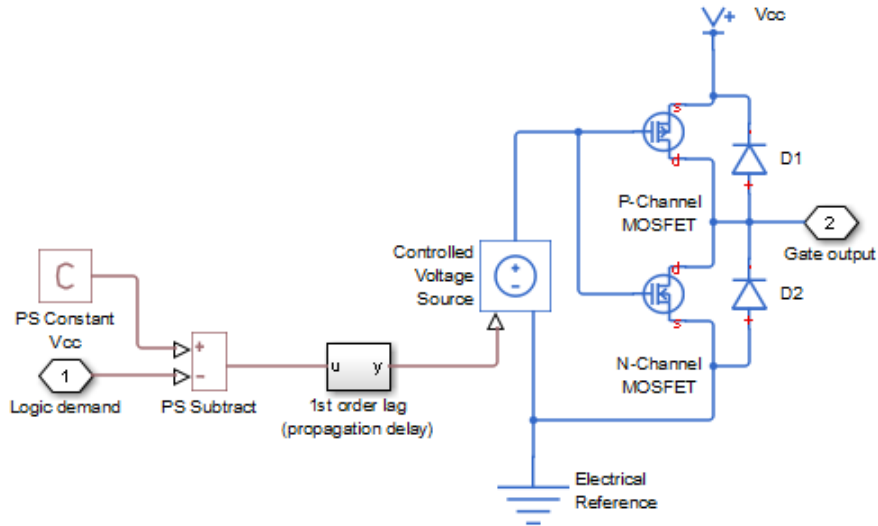
Available Output Models

The blocks in the Logic sublibrary of the Integrated Circuits library provide a choice of two output models:

- **Linear** — Models the gate output as a voltage source driving a series resistor and capacitor connected to ground. This is suitable for logic circuit operation under normal conditions and when the logic gate drives other high-impedance CMOS gates. The block sets the value of the gate output capacitor such that the resistor-capacitor time constant equals the **Propagation delay** parameter value. The linear output model is shown in the following illustration.



- **Quadratic** — Models the gate output in terms of a complementary N-channel and P-channel MOSFET pair. This adds more fidelity, which becomes relevant if drawing higher currents from the gate output, or if exercising the gate under fault conditions. In addition, the gate input demand is lagged to approximate the **Propagation delay** parameter value. Default parameters are representative of the 74HC logic gate family. The quadratic output model is shown in the next illustration.



Use the **Output current-voltage relationship** parameter on the **Outputs** tab of the block dialog box to specify the output model.

For most system models, MathWorks recommends selecting the linear option because it supports faster simulation. If necessary, you can use the more detailed output model to validate simulation results obtained from the simpler model.

Quadratic Model Output and Parameters

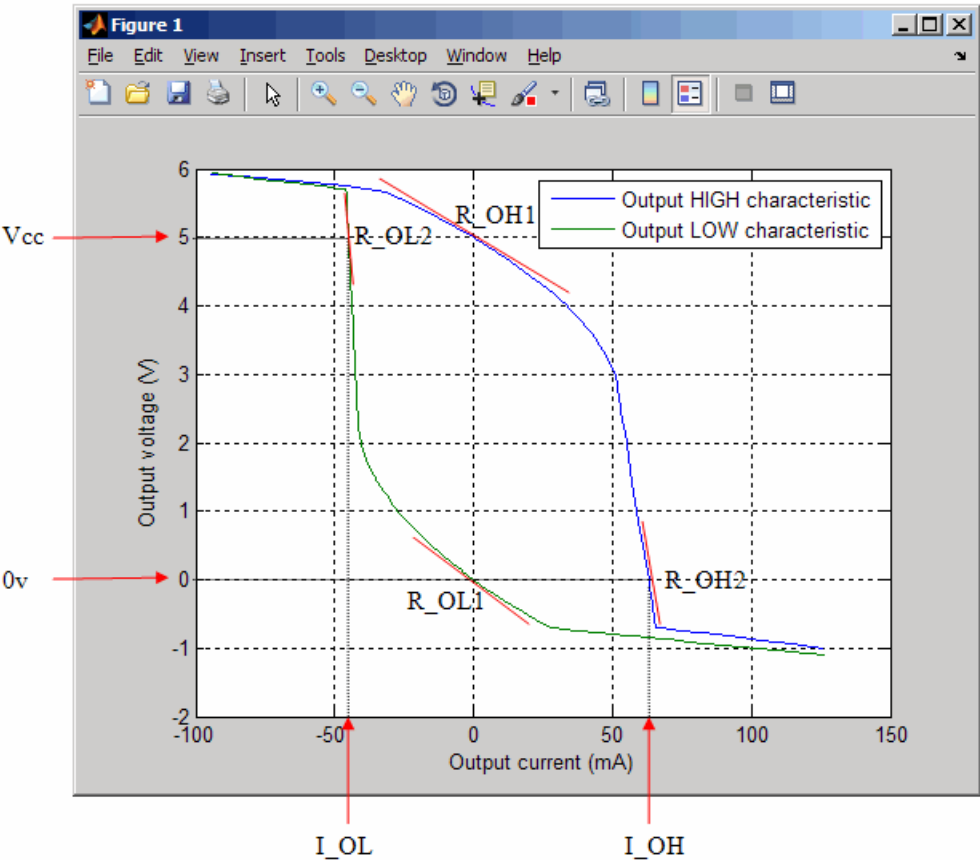
If you select the quadratic model, use the following parameters to control the block output:

- **Supply voltage** — Supply voltage value (V_{cc}) applied to the gate in your circuit. The default value is 5 V.
- **Measurement voltage** — The gate supply voltage for which mask data output resistances and currents are defined. The default value is 5 V.
- **Logic HIGH output resistance at zero current and at I_{OH}** — A row vector $[R_{OH1} R_{OH2}]$ of two resistance values. The first value R_{OH1} is the gradient of the output voltage-current relationship when the gate is logic HIGH and there is no output current. The second value R_{OH2} is the gradient of the output voltage-current

relationship when the gate is logic HIGH and the output current is I_{OH} . The default value is [25 250] Ω .

- **Logic HIGH output current I_{OH} when shorted to ground** — The resulting current when the gate is in the logic HIGH state, but the load forces the output voltage to zero. The default value is 63 mA.
- **Logic LOW output resistance at zero current and at I_{OL}** — A row vector [R_{OL1} R_{OL2}] of two resistance values. The first value R_{OL1} is the gradient of the output voltage-current relationship when the gate is logic LOW and there is no output current. The second value R_{OL2} is the gradient of the output voltage-current relationship when the gate is logic LOW and the output current is I_{OL} . The default value is [30 800] Ω .
- **Logic LOW output current I_{OL} when shorted to Vcc** — The resulting current when the gate is in the logic LOW state, but the load forces the output voltage to the supply voltage Vcc. The default value is -45 mA.
- **Propagation delay** — Time it takes for the output to swing from LOW to HIGH or HIGH to LOW after the input logic levels change. For quadratic output, it is implemented by the lagged gate input demand. The default value is 25 ns.
- **Protection diode on resistance** — The gradient of the voltage-current relationship for the protection diodes when forward biased. The default value is 5 Ω .
- **Protection diode forward voltage** — The voltage above which the protection diode is turned on. The default value is 0.6 V.

The following graphic illustrates the quadratic output model parameterization, using the default parameter output characteristics for a +5V supply.



Simulating Thermal Effects in Semiconductors

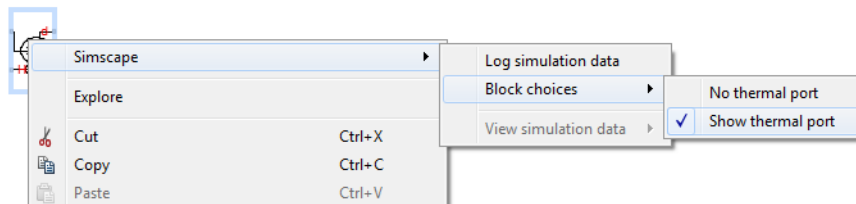
In this section...

- “Using the Thermal Ports” on page 2-24
- “Thermal Model for Semiconductor Blocks” on page 2-26
- “Thermal Mass Parameterization” on page 2-27
- “Electrical Behavior Depending on Temperature” on page 2-27
- “Improving Numerical Performance” on page 2-28

Using the Thermal Ports

Certain Simscape Electronics blocks, for example, the blocks in the Semiconductors library, contain an optional thermal port. This port is hidden by default. If you want to simulate the generated heat and device temperature, expose the thermal port on a particular block instance in your block diagram:

- 1 Right-click the block where you want to show the thermal port.
- 2 From the context menu, select **Simscape > Block choices > Show thermal port**.



When the thermal port is exposed, the block dialog box contains an additional tab, **Thermal Port**. For semiconductor devices, the tab always contains the same set of parameters.

Settings

Main Ohmic Resistance Junction Capacitance Temperature Dependence Thermal Port

Junction-case and case-ambient (or case-heatsink) thermal resistances, [R_JC R_CA]: [0 10] K/W

Thermal mass parameterization: By thermal time constants

Junction and case thermal time constants, [t_J t_C]: [0 10] s

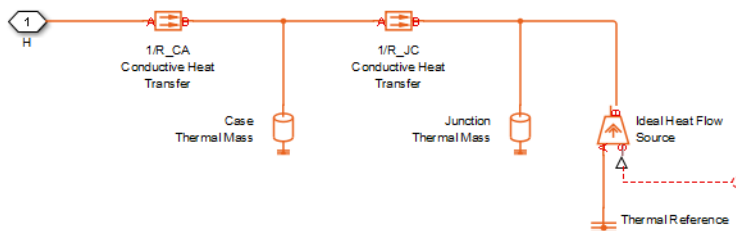
Junction and case initial temperatures, [T_J T_C]: [25 25] degC

- Junction case and case-ambient (or case-heatsink) thermal resistances, [R_JC R_CA]** — A row vector [R_JC R_CA] of two thermal resistance values, represented by the two Conductive Heat Transfer blocks in the “Thermal Model for Semiconductor Blocks” on page 2-26. The first value R_JC is the thermal resistance between the junction and case. The second value R_CA is the thermal resistance between port H and the device case. See “Thermal Model for Semiconductor Blocks” on page 2-26 for further details. The default value is [0 10]K/W.
- Thermal mass parameterization** — Select whether you want to parameterize the thermal masses in terms of thermal time constants (By thermal time constants), or specify the thermal mass values directly (By thermal mass). For more information, see “Thermal Mass Parameterization” on page 2-27. The default is By thermal time constants.
- Junction and case thermal time constants, [t_J t_C]** — A row vector [t_J t_C] of two thermal time constant values. The first value t_J is the junction time constant. The second value t_C is the case time constant. This parameter is only visible when you select By thermal time constants for the **Thermal mass parameterization** parameter. The default value is [0 10] s.
- Junction and case thermal masses, [M_J M_C]** — A row vector [M_J M_C] of two thermal mass values. The first value M_J is the junction thermal mass. The second value M_C is the case thermal mass. This parameter is only visible when you select By thermal mass for the **Thermal mass parameterization** parameter. The default value is [0 1] J/K.
- Junction and case initial temperatures, [T_J T_C]** — A row vector [T_J T_C] of two temperature values. The first value T_J is the junction initial temperature. The second value T_C is the case initial temperature. The default value is [25 25] °C.

For more information on selecting the parameter values, see “Thermal Model for Semiconductor Blocks” on page 2-26 and “Improving Numerical Performance” on page 2-28. For explanation of the relationship between the **Thermal Port** and **Temperature Dependence** tabs in a block dialog box, see “Electrical Behavior Depending on Temperature” on page 2-27.

Thermal Model for Semiconductor Blocks

All blocks with optional thermal ports include an internal thermal model with thermal masses and resistances. The purpose of including this model internally is to keep your diagram uncluttered by the thermal model. The following figure shows an equivalent model of the internal thermal model for semiconductor devices.



The port H in the diagram corresponds to the thermal port H of the block. The two Thermal Mass blocks represent the thermal mass of the device case and the thermal mass of the semiconductor junction, respectively. The Ideal Heat Flow Source block inputs heat to the model with value equal to the electrically generated heat from the device.

The two Conductive Heat Transfer blocks model the thermal resistances. Resistance R_{JC} (conductance $1/R_{JC}$) represents the thermal resistance between junction and case. Because of this resistance, under normal conditions the junction will be hotter than the case. Resistance R_{CA} represents the thermal resistance between port H and the device case. If the device has no heatsink, then in your model you should connect port H to an Ideal Temperature Source with its temperature set to ambient conditions. If your device does have an external heatsink, then you must model the heatsink externally to the device, and connect the heatsink thermal mass directly to port H.

If you wish to keep all or part of the thermal model of the device external to the model, you can set the necessary block parameters to zero. The following rules apply:

- Case thermal mass must be greater than zero.

- Junction thermal mass can only be set to zero if the junction-case resistance is also set to zero.
- If both case and junction thermal masses are defined, but junction-case resistance is zero, then the initial temperatures assigned to junction and case must be identical.

Thermal Mass Parameterization

Datasheets usually quote both of the thermal resistances, but rarely give values for thermal masses. There are two parameterization options for the thermal masses:

- By `thermal time constants` — Parameterize the thermal masses in terms of thermal time constants. This is the default.
- By `thermal mass` — Specify the thermal mass values directly.

The thermal time constants t_J and t_C are defined as follows:

$$t_J = M_J \cdot R_{JC}$$

$$t_C = M_C \cdot R_{CA}$$

where M_J and M_C are the junction and case thermal masses, respectively, R_{JC} is the thermal resistance between junction and case, and R_{CA} is the thermal resistance between port H and the device case.

You can determine the case time constant by experimental measurement. If data is not available for the junction time constant, you can either omit it and set the junction-case resistance to zero, or you can set the junction time constant to a typical value of one tenth of the case time constant. The alternative is to estimate thermal masses based on device dimensions and averaged material specific heats.

Electrical Behavior Depending on Temperature

For blocks with optional thermal ports, there are two simulation options:

- Simulate the generated heat, device temperature, and the effect of temperature on the electrical equations.
- Simulate the generated heat and device temperature, but do not include effect of temperature on the electrical equations. Use this option when the impact of temperature on the electrical equations is small over the temperature range to be

simulated, or where the primary task of the simulation is to capture the heat generated to support system-level design.

The thermal port and the **Thermal Port** tab of the block dialog box let you simulate the generated heat and device temperature. The **Thermal Dependence** tab of the block dialog box lets you model the effect of temperature of the semiconductor junction on the electrical equations. Therefore:

- To simulate all the temperature effects, show the block's thermal port and set the **Parameterization** parameter on the **Thermal Dependence** tab to Model temperature dependence (or, for blocks with a choice of options for modeling temperature dependence, select one of these options, for example, Use an I-V data point at second measurement temperature).
- To simulate just the generated heat and device temperature, show the block's thermal port but set the **Parameterization** parameter on the **Thermal Dependence** tab to None – Simulate at parameter measurement temperature.

Improving Numerical Performance

It is very important that you set realistic values for thermal masses and resistances. Otherwise, junction temperatures can become extreme, and out of range for valid results, which in turn may manifest itself as numerical difficulties when simulating. A simple test to see if numerical difficulties are a result of unrealistic thermal values is to turn off the temperature dependence for the electrical equations, by setting the **Parameterization** parameter on the **Thermal Dependence** tab to None – Simulate at parameter measurement temperature.

The thermal time constants are generally much slower than electrical time constants, so the thermal aspects of your model are unlikely to dictate the maximum fixed time step you can simulate at (for example, for hardware-in-the-loop simulations). However, if you need to remove detail (for example, to speed up simulation), the junction thermal mass time constant is typically an order of magnitude faster than the case thermal mass time constant. You can remove the effect of the junction thermal mass by setting the junction thermal mass to zero and also setting the junction-case thermal resistance to zero.

Simulating Thermal Effects in Rotational and Translational Actuators

In this section...

“Using the Thermal Ports” on page 2-29

“Thermal Model for Actuator Blocks” on page 2-31

Using the Thermal Ports

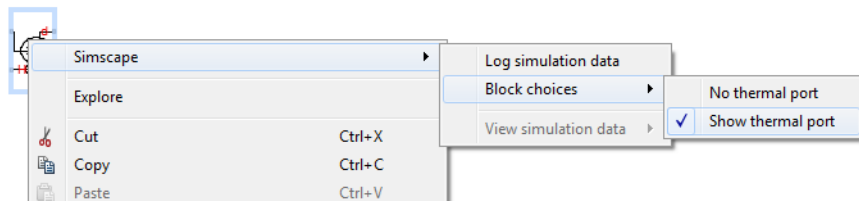
All blocks that represent rotational and translational actuators with electrical windings can optionally show a thermal port for each electrical winding. So, for example:

- A DC Motor block can optionally show a single thermal port corresponding to the armature
- A Shunt Motor block can optionally show two thermal ports, one for the stator winding and one for the field winding

The thermal port represents copper resistance losses which convert electrical power to heat. These losses are sometimes referred to as i^2R losses. The thermal ports do not represent iron losses due to, for example, Eddy currents and hysteresis.

The thermal ports are hidden by default. To expose the thermal port on a particular block instance in your block diagram:

- 1 Right-click the block where you want to show the thermal port.
- 2 From the context menu, select **Simscape > Block choices > Show thermal port**.



When the thermal port is exposed, the block dialog box contains two additional tabs, **Temperature Dependence** and **Thermal Port**. For actuator blocks with single winding, these tabs always contain the same set of parameters.

Settings

Electrical Torque Mechanical Temperature Dependence Thermal Port

Resistance temperature coefficient: 0.00393 1/K

Measurement temperature: 25 degC

- **Resistance temperature coefficient** — Parameter α in the equation defining resistance as a function of temperature, as described in “Thermal Model for Actuator Blocks” on page 2-31. The default value is for copper, and is 0.00393 1/K.
- **Measurement temperature** — The temperature for which motor parameters are defined. The default value is 25 °C.

Settings

Electrical Torque Mechanical Temperature Dependence Thermal Port

Thermal mass: 100 J/K

Initial temperature: 25 degC

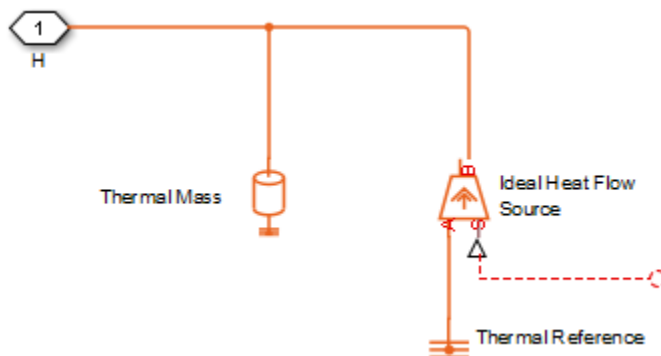
- **Thermal mass** — Thermal mass of the electrical winding, defined as the energy required to raise the temperature by one degree. The default value is 100 J/K.
- **Initial temperature** — The temperature of the thermal port at the start of simulation. The default value is 25 °C.

For more information on selecting the parameter values, see “Thermal Model for Actuator Blocks” on page 2-31.

Parameters for actuator blocks with two windings differ, and are described on the respective block reference pages.

Thermal Model for Actuator Blocks

The following illustration shows the thermal port model used by the actuator blocks. The heat generated by the copper windings is provided as an input to the S physical signal input port of the Ideal Heat Flow Source. The thermal mass represents the lumped thermal mass of the copper winding where thermal mass is defined as the energy required to raise its temperature by one degree. If the mass is denoted M and the specific heat capacity is c_p , then thermal mass is $M \cdot c_p$.



Winding resistance is assumed linearly dependent on temperature, and is given by:

$$R = R_0 (1 + \alpha (T - T_0))$$

where:

- R is the resistance at temperature T .
- R_0 is the resistance at the measurement (or reference) temperature T_0 .
- α is the resistance temperature coefficient. A typical value for copper is 0.00393/K.

Plot Basic Characteristics for Semiconductor Blocks

A quick plot feature lets you visualize the basic I-V characteristics for semiconductor switching devices, based on the current block parameter values.

This feature is implemented for nonthermal variants of the following blocks in the Semiconductors library:

- N-Channel IGBT
- N-Channel MOSFET (both threshold-based and surface-potential-based variants)
- P-Channel MOSFET (both threshold-based and surface-potential-based variants)
- N-Channel LDMOS FET
- P-Channel LDMOS FET
- N-Channel JFET
- P-Channel JFET
- NPN Bipolar Transistor
- PNP Bipolar Transistor

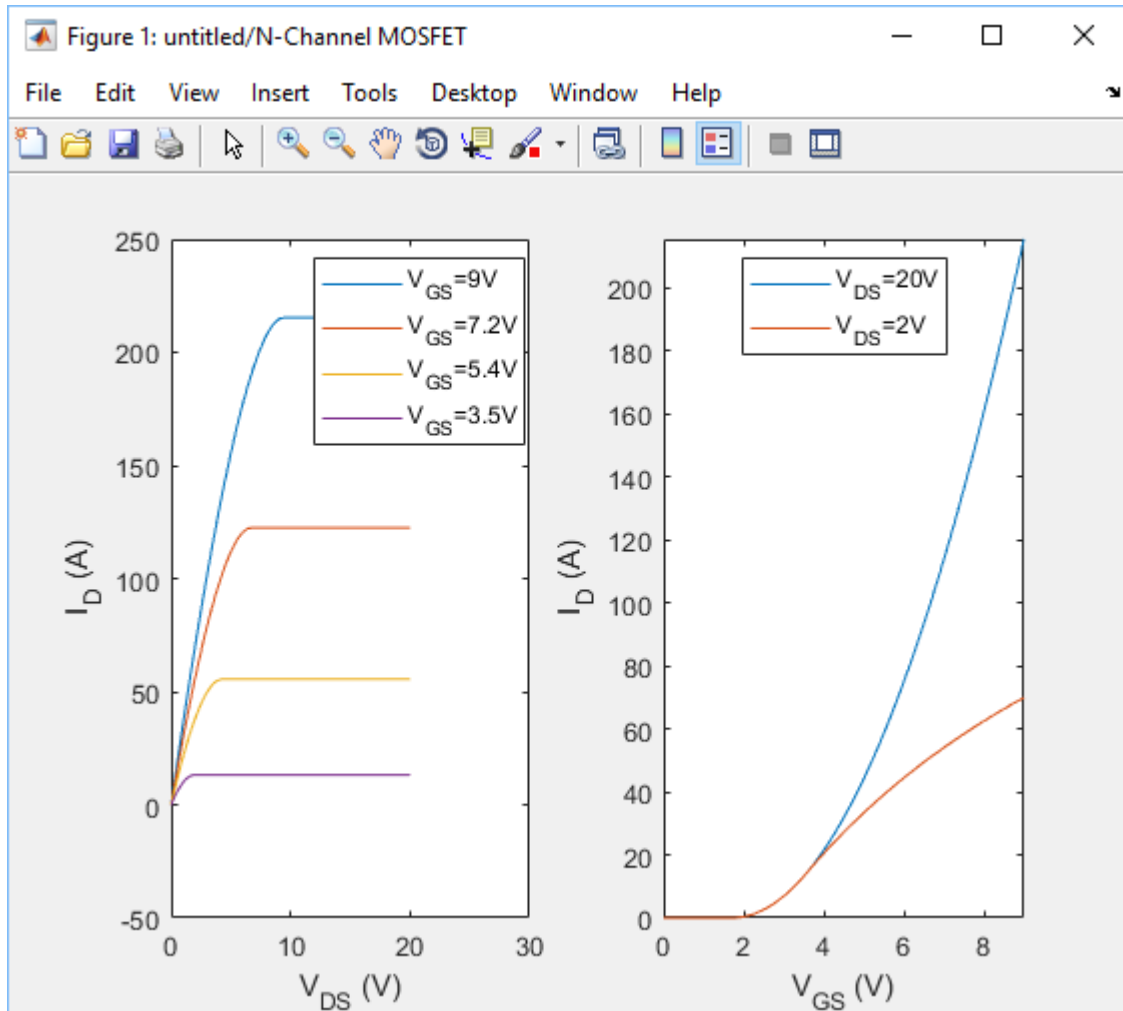
To plot the characteristics, right-click an appropriate semiconductor block in your model and, from the context menu, select **Electronics > Basic characteristics**.

Note For surface-potential-based N-Channel MOSFET and P-Channel MOSFET blocks, the **Electronics > Explore characteristics** option is also available. This option opens the Characteristics Viewer tool, which lets you perform an in-depth study of block characteristics and match the block behavior to a set of target characteristics. For more information, see “MOSFET Characteristics Viewer” on page 2-35.

To plot the basic characteristics:

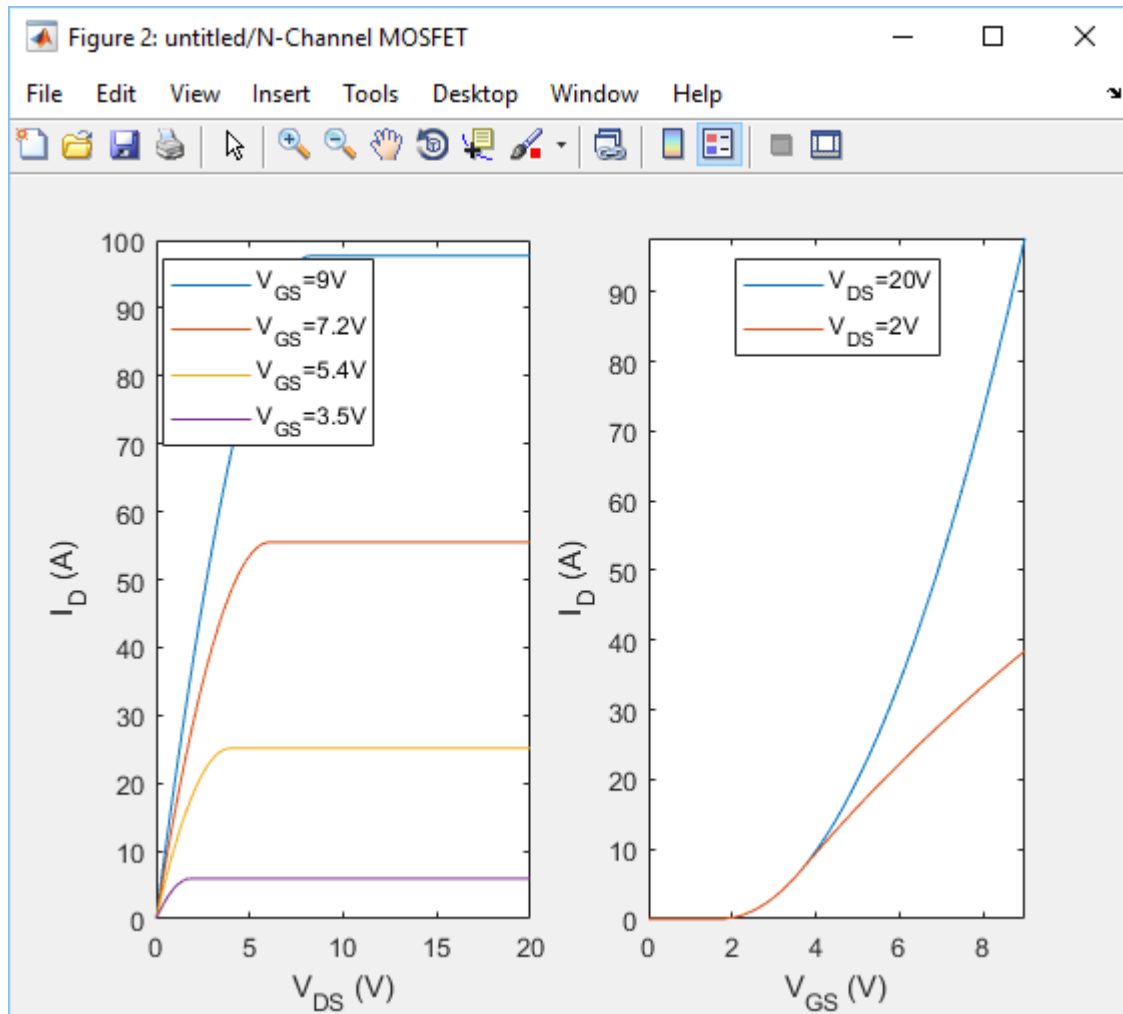
- 1 Right-click a semiconductor block in your model and, from the context menu, select **Electronics > Basic characteristics**. The software automatically computes a set of bias conditions, based on the block parameter values, and opens a figure window containing a plot of the DC I-V characteristics for the block.

For example, the following plot corresponds to the default parameter values of a threshold-based N-Channel MOSFET block.



- 2 If you change the block parameter values and plot the characteristics again, the plot opens in a new window. This way, you can compare the plots side-by-side and see how the parameter values affect the resulting DC I-V characteristics for the block.

For example, if you change the **Gate-source voltage, V_{GS} , for $R_{DS(on)}$** parameter value to 20 V, the new plot looks like this.



See Also

More About

- “MOSFET Characteristics Viewer” on page 2-35

MOSFET Characteristics Viewer

In this section...

“Suggested Workflow” on page 2-35

“Add and Manage Characteristics” on page 2-37

“Choose Parameters and Generate Plots” on page 2-40

“Save the Results” on page 2-42

The Characteristics Viewer tool lets you study characteristics of a particular parameterization of a surface-potential-based MOSFET block and match the block behavior to a set of target characteristics. The tool allows you to:

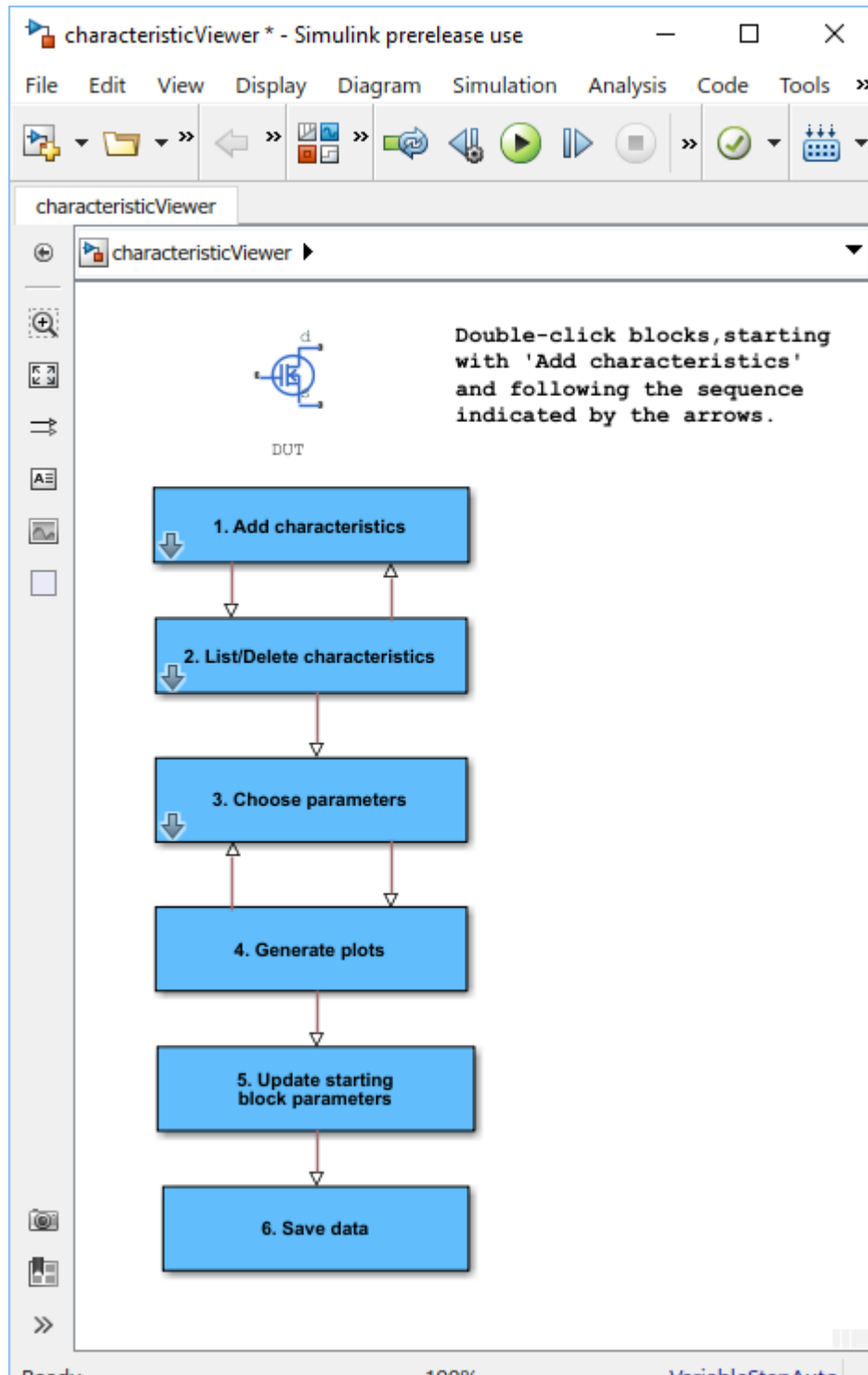
- Plot simulated data, using the current block parameters.
- Overlay simulated data plots over tabulated target data.
- Modify block parameters.
- When satisfied with the results of the parameters tuning in the Characteristics Viewer, update the block parameters in the model.
- Save generated parameter sets for future reuse in a different model.

Suggested Workflow

The Characteristics Viewer tool is available for surface-potential-based N-Channel MOSFET or P-Channel MOSFET blocks only. To switch to a surface-potential-based variant when you add an N-Channel MOSFET or P-Channel MOSFET block from the library, right-click the block in your model and, from the context menu, select **Simscape > Block choices > Surface-potential-based**. Then, when you right-click the block again, the context menu will contain the **Electronics** option, necessary to start the parameterization tool.

To use the MOSFET parameterization tool:

- 1 Right-click a surface-potential-based MOSFET block in your model and, from the context menu, select **Electronics > Explore characteristics**. A `charactericViewer` window opens.



- 2 Double-click **Add characteristics**. Specify the characteristics type (target, simulated, or both), and the desired values. Click **Add to plot**.

Continue adding more characteristics, as needed. The **Replace plot** button lets you replace previously added plots. You can also use the **List/Delete characteristics** block, iteratively with **Add characteristics**, to configure your characteristics set.

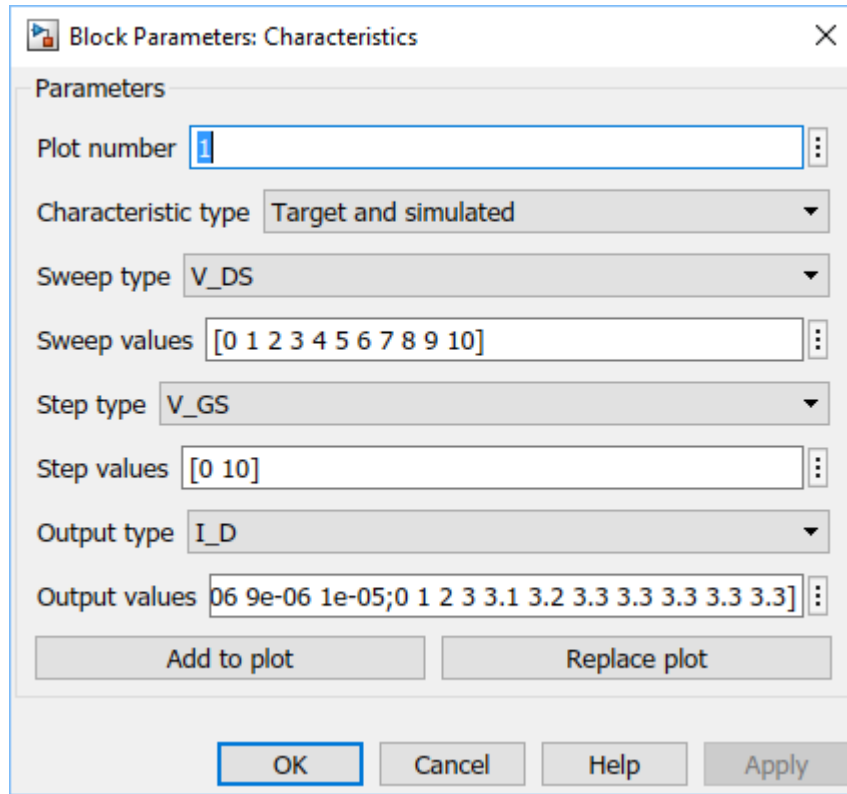
- 3 Double-click **Choose parameters** and select the parameters of interest.
- 4 Double-click **Generate plots**.
- 5 Iterate between the previous two steps to tune the parameters by matching the simulation results to the target curves.
- 6 When satisfied with the results of the parameters tuning, double-click **Update starting block parameters** to update the block parameters in your model. Until you perform this step, the block in the original model is not affected.
- 7 You can double-click **Save data** to save the generated characteristics as a MAT-file, for future reuse in a different model.

Add and Manage Characteristics

You start the MOSFET parameters tuning process by specifying the desired set of target characteristics:

- 1 In the characteristicViewer window, double-click **Add characteristics**.

The Characteristics window opens.



- 2 Enter **Plot number**. This number defines the number of the figure that the characteristic will be plotted on. It allows you to add multiple characteristics to the same figure, for overlaying characteristics on top of each other. However, the figure will comprise one xy -axis only.
- 3 Specify the **Characteristic type**:
 - **Target only** — The plot will contain data that you specified, in terms of both input and output values. No simulation will be performed in this case. The data will simply be added to the appropriate plot.
 - **Simulated only** — The plot will contain data that is a result of a simulation over the input bias conditions that you specify.
 - **Target and simulated** — The plot will contain both types of data. This option is useful if you are trying to adjust parameters for the model to fit data that you have extracted from a datasheet.

- 4 Select **Sweep type**, which defines the x -axis variable for the resultant plot:
 - V_{GS} — Sweep over the gate-source voltage.
 - V_{DS} — Sweep over the drain-source voltage.
 - I_D — Sweep over the drain current. Normally, the drain current is not a typical input for a characteristic sweep.
- 5 If the **Characteristic type** is **Simulated only**, specify **Sweep range**. This is a vector of values indicating the range for the swept variable. Only the minimum and maximum values of this vector are utilized by the tool, since the exact sample points for the output data are determined by the variable-step simulation.
- 6 If the **Characteristic type** is **Target only** or **Target and simulated**, specify **Sweep values**. This is a vector of values for the swept variable at which the output is sampled for the target data. As an example, for an I_D - V_{DS} characteristic extracted from a datasheet, the vector would contain the V_{DS} values corresponding to the sampled I_D values in the target curve.
- 7 Select **Step type** to define the second independent input bias condition. The choices are the same as for **Sweep type**. For example, if an I_D - V_{DS} curve is defined as being at a constant V_{GS} , choose V_{GS} for **Step type**.
- 8 Use **Step values** to specify the values for the stepped variable. For example, if an I_D - V_{DS} curve is desired for V_{GS} values of 0 and 10V, set **Step type** to V_{GS} and **Step values** to [0 10].
- 9 Select **Output type**, which defines the output measurement for the characteristic. This is the y -axis variable for the resultant plot. The available values are: V_{GS} , V_{DS} , I_D , C_{GG} , C_{GD} , C_{DG} , and C_{DD} . The capacitances C_{GG} , C_{GD} , C_{DG} , and C_{DD} are defined according to their terminals. To relate these quantities to the datasheet parameters of C_{iss} , C_{rss} and C_{oss} , note that $C_{GG} = C_{iss}$, $C_{DD} = C_{oss}$, and $C_{GD} = C_{rss}$ at $V_{GS} = 0$.

 V_{GS} is not a good choice as an output for the surface-potential-based MOSFET model. This value is provided in anticipation of using this tool for other device types.
- 10 If the **Characteristic type** is **Target only** or **Target and simulated**, specify **Output values**. This is the target data that you want to plot in the figures. Provide this data as an m -by- n matrix, where m is the size of **Step values** and n is the size of **Sweep values**.
- 11 Click **Add to plot** to add the characteristic specification to the appropriate **Plot number**.
- 12 Continue adding more characteristics, as needed.

The **Replace plot** button lets you replace previously added plots. You can also use the **List/Delete characteristics** block, iteratively with **Add characteristics**, to configure your characteristics set.

Choose Parameters and Generate Plots

After you have specified the desired set of target characteristics, the next step is to define the parameters for the MOSFET block:

- 1 In the characteristicViewer window, double-click **Choose parameters**.

Block Parameters: Tuner

VT DC AC T FIXED EXTRAS

gamma ($V^{0.50000}$)

0.0 7.0

3.5

min

0

max

7

phib2ref (V)

0.0 2.0

1

min

0

max

2

OK Cancel Help Apply

The Tuner window opens. It contains a series of sliders on different tabs, according to which feature of the MOSFET characteristics is most impacted by the specific parameter:

- The **VT** tab displays parameters that primarily impact the threshold voltage (**gamma** and **phib2ref**).
 - The parameters on the **DC** tab primarily affect the DC characteristics.
 - The parameters on the **AC** tab primarily affect the MOSFET dynamics.
 - The parameters on the **T** tab affect temperature scaling.
 - The parameters on the **FIXED** tab are generally fixed at some particular value that is not easy to derive from the displayed characteristics, such as the simulation temperature and the gate resistance (which is often indicated directly on datasheets).
 - The **EXTRAS** tab contains other parameters, which impact the characteristics in ways similar to parameters that already appear on other tabs. For example, **Rsref** (the series resistance associated with the source) operates similarly to **betaref** from the **DC** tab. As a result, it is not always possible to disentangle these two effects.
- 2 Use the sliders on the appropriate tabs of the Tuner dialog.

You can modify the `min` and `max` values, as needed, because they simply define the range over which the various sliders work. These values have no meaning for the underlying model parameters. Changing a `min` or `max` value automatically updates the slider range, without needing to click **OK** or **Apply**.

- 3 After adjusting the sliders, generate the plots to see how close the simulation data is to the target data. In the `charactericViewer` window, double-click **Generate plots**.
- 4 Iterate between tuning the parameters and generating plots until the simulation results match the target curves.

Save the Results

Once you are satisfied with the results of the parameters tuning:

- Double-click **Update starting block parameters** to update the block parameters in your model. Until you perform this step, the block in the original model is not affected.

Note For this step to work, the original model must stay open while you are tuning the parameters.

- You can also double-click **Save data** to save the generated characteristics as a MAT-file, for future reuse in a different model. Specify the file name for saving the data. Inside the file, all the data is saved in an object named `parameterHelper`.

To apply the parameters stored in this object to another MOSFET block, select the MOSFET block in a model and, in the MATLAB Command Window, type:

```
parameterHelper.parameters.updateBlockParameters(gcbh)
```

This command applies the parameter values to the block defined by the handle `gcbh`.

You can also use a string instead of the block handle, for example:

```
parameterHelper.parameters.updateBlockParameters(gcb)
```

To inspect the parameters directly, type `parameterHelper.parameters.values` for the values (stored as character vectors) or `parameterHelper.parameters.names` for the names.

See Also

More About

- Interactive Generation of MOSFET Characteristics
- “Plot Basic Characteristics for Semiconductor Blocks” on page 2-32

